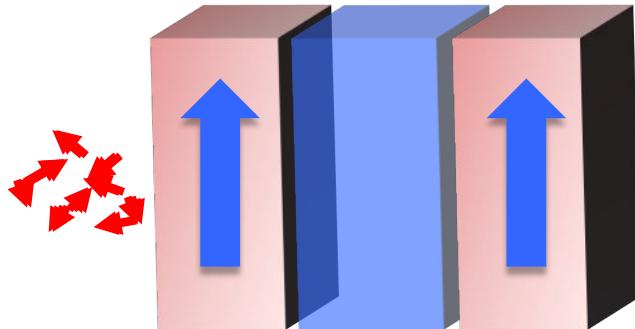


# Spin Transport: GMR, TMR etc.

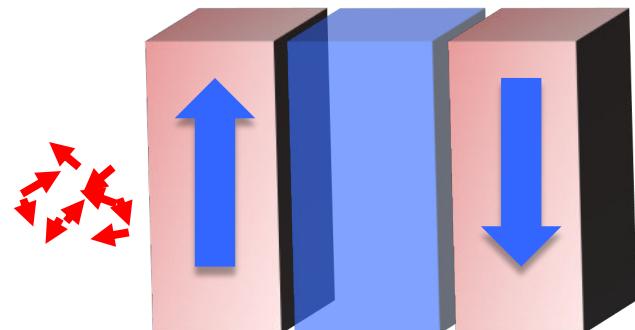


by Aurélien Manchon  
[physiquemanchon.wixsite.com](http://physiquemanchon.wixsite.com)

# Spintronics: a success story



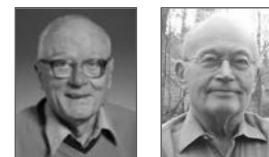
Giant magnetoresistance - 1988



Spin transfer torque - 1996

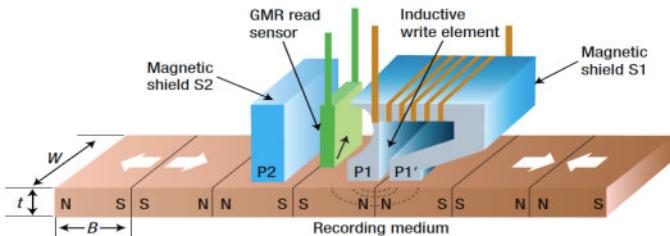


Fert & Grünberg  
Nobel Laureates 2007

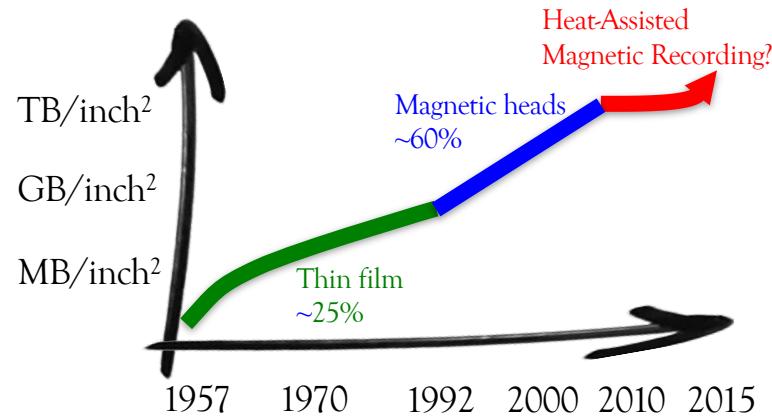
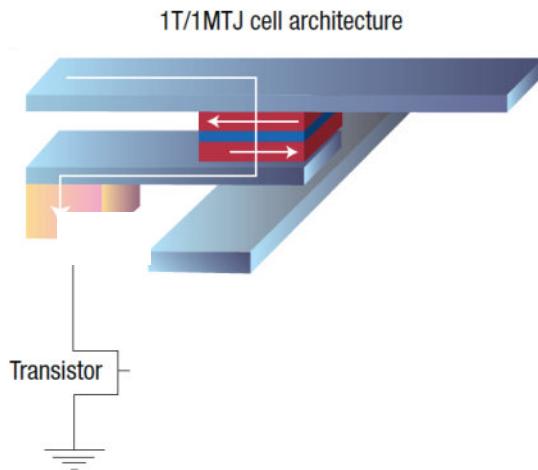


Berger &  
Slonczewski  
Buckley prize 2013

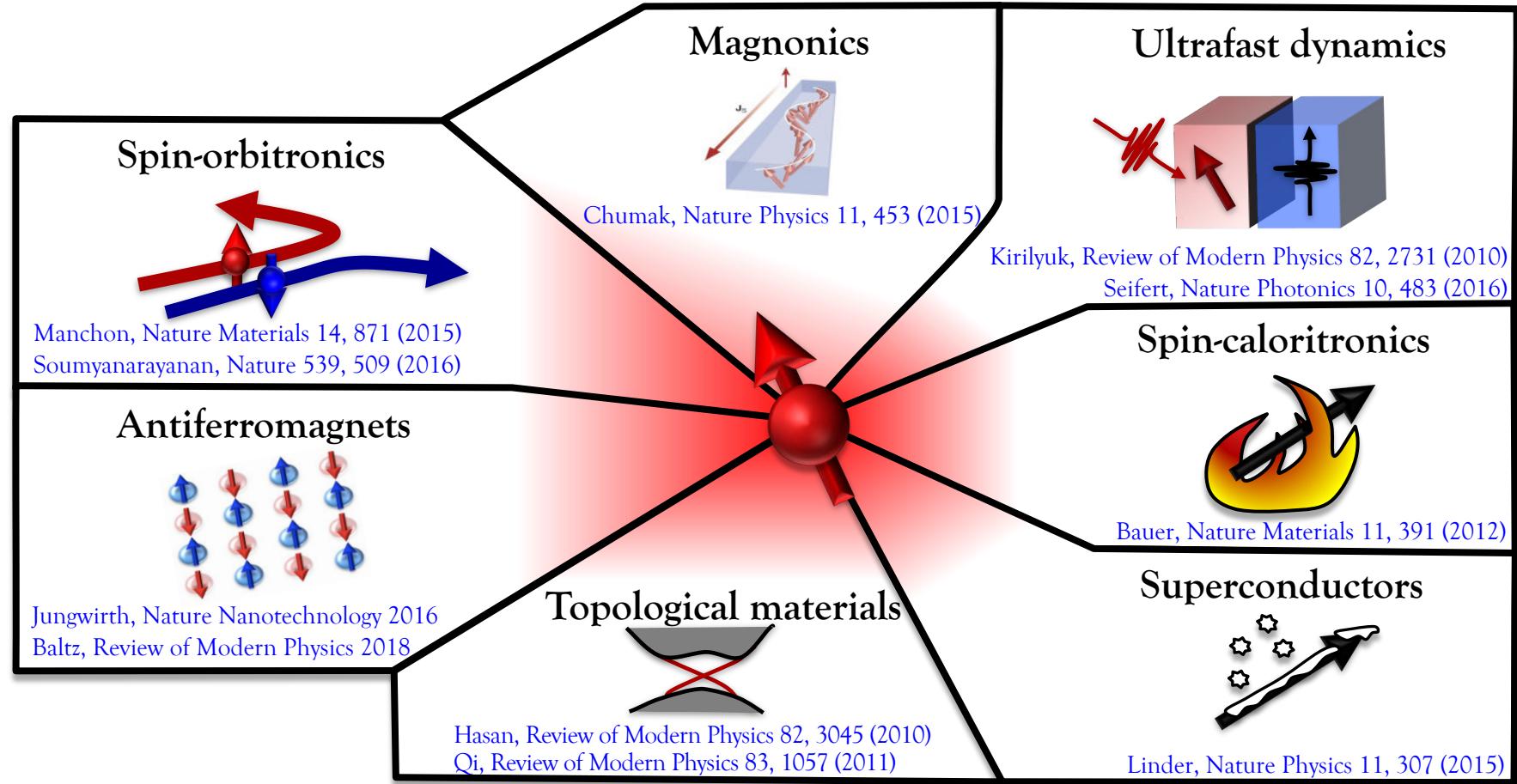
# Spintronics: a success story

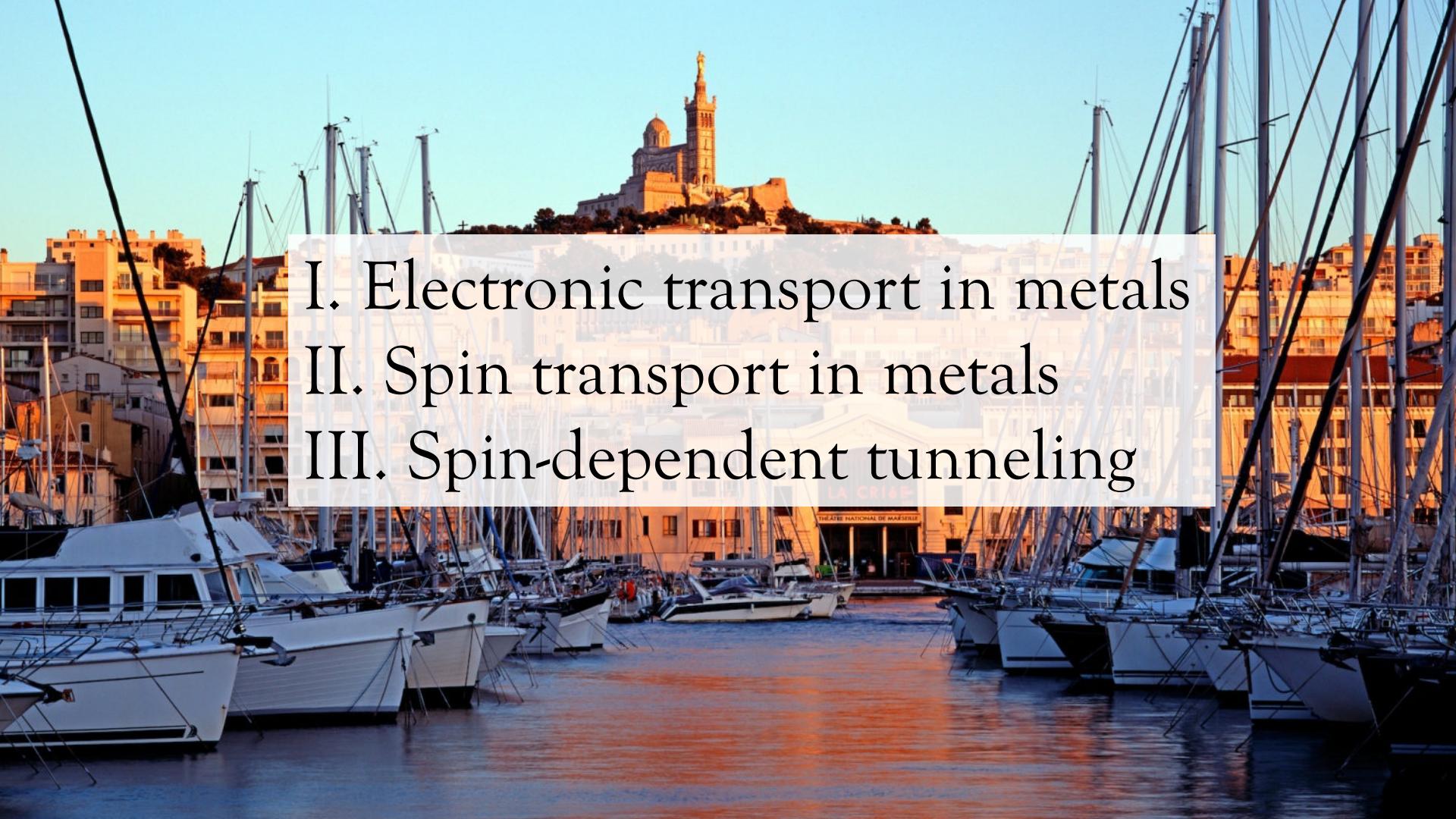


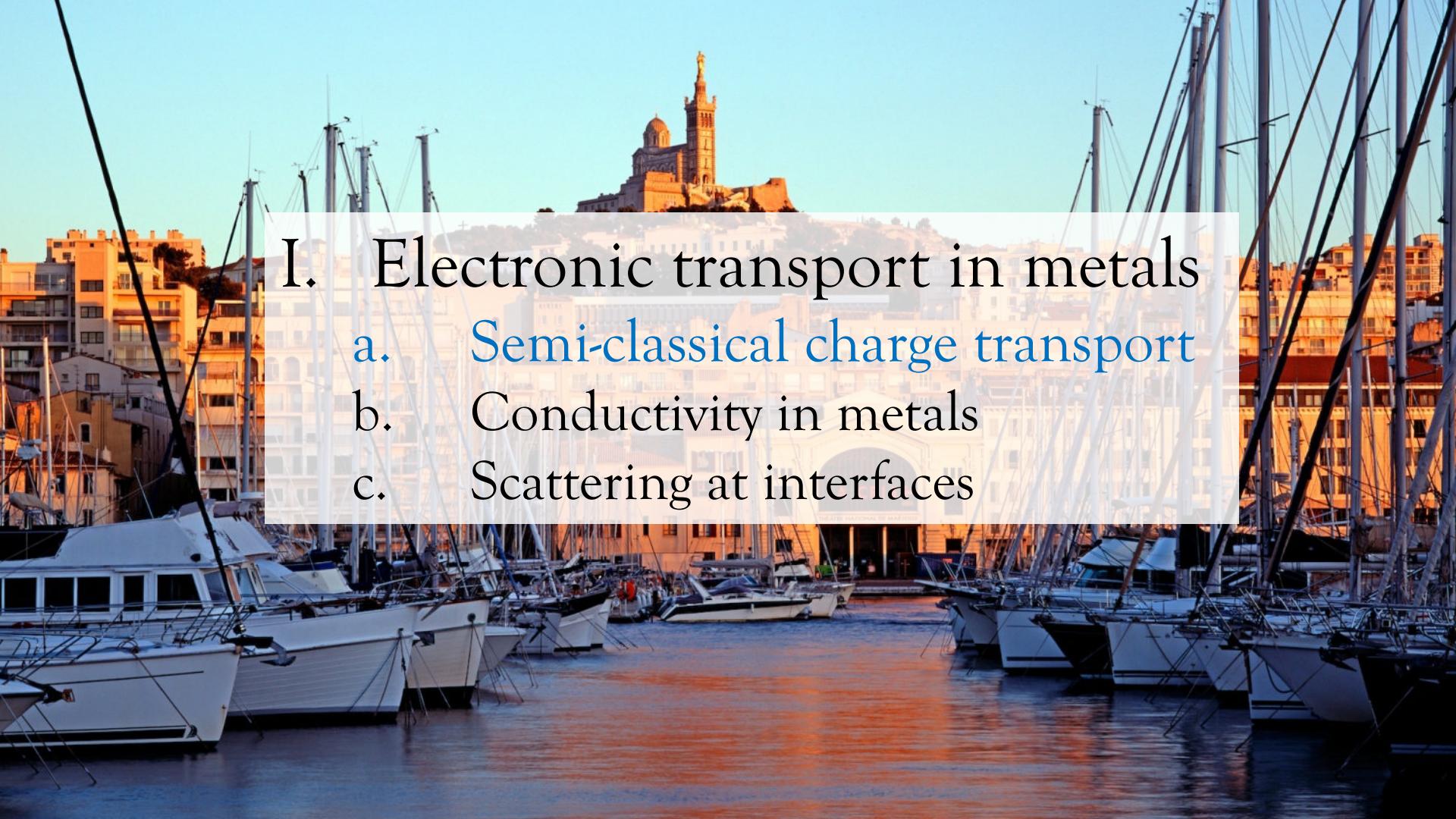
Chappert et al., Nature Materials 2007



Major semiconductor bigfoot: IBM,  
Samsung, Intel, Toshiba, Qualcom etc.



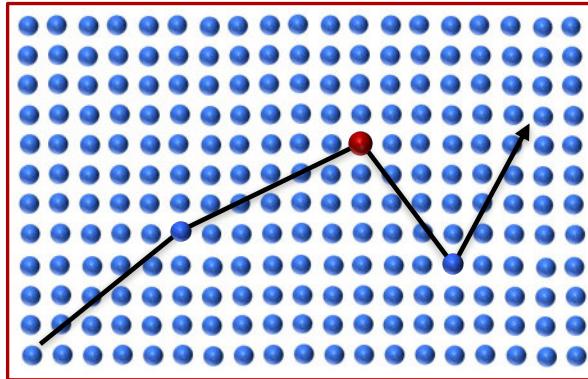
- 
- I. Electronic transport in metals  
II. Spin transport in metals  
III. Spin-dependent tunneling

- 
- I. Electronic transport in metals
- a. Semi-classical charge transport
  - b. Conductivity in metals
  - c. Scattering at interfaces

# a. Semi-classical charge transport

## Drude's model for charge conduction

The electron is a classical **Boltzmann particle** scattering with the ions of the crystal



If the Fermi wavelength of the electronic wave is much shorter than the mean free path and the size of the system,  $\lambda_F \ll \lambda, d \dots$   
Drude's classical picture is acceptable

Newton's equation of motion

$$\frac{\partial \mathbf{p}}{\partial t} = -e\mathbf{E} - \frac{\mathbf{p}}{\tau} \quad e > 0$$

Electron's momentum  
Electric field  
Momentum relaxation

$$\mathbf{j}_c = -\frac{en}{m}\mathbf{p} = \tau \frac{e^2 n}{m} \mathbf{E}$$

$$\sigma_c = \tau \frac{e^2 n}{m}$$

Drude conductivity



Paul Drude

### a. Semi-classical charge transport

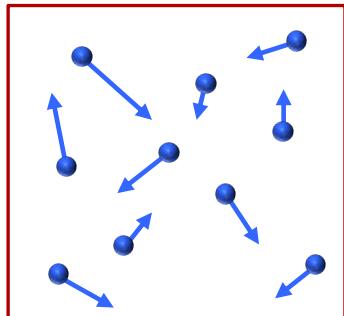
## Boltzmann transport equation

The electron cloud is represented by a statistical distribution over the **position** and **velocity**  $f = f(\mathbf{r}, \mathbf{v}, t)$



Ludwig Boltzmann

## The semiclassical electron gas



E1

## Cloud's dynamics

$$\frac{df}{dt} = \left. \frac{df}{dt} \right|_{\text{coll}} \xrightarrow{\text{collision integral, relaxes } f \text{ towards equilibrium}}$$

► collision integral, relaxes  $\rho$  towards equilibrium

$$\frac{df}{dt} =$$

$(v \cdot \partial_t)$

$E \cdot v)$   $\partial_{\varepsilon} f f$   
  
 acceleration = force

$$\frac{df}{dt}\Big|_{\text{coll}} = -\frac{f - f_0}{\tau}$$

## a. Semi-classical charge transport

Boltzmann transport equation

$$\partial_t f + (\mathbf{v} \cdot \partial_{\mathbf{r}}) f - (e \mathbf{E} \cdot \mathbf{v}) \partial_{\varepsilon} f = -\frac{f - f_0}{\tau}$$

We now assume that  $f = f_0 + \delta f$

 Non-equilibrium (linear in  $\mathbf{v}$ )  
Equilibrium (Fermi-Dirac)

In steady state, we obtain  $\delta f = \underbrace{\tau(e \mathbf{E} \cdot \mathbf{v}) \partial_{\varepsilon} f}_{\text{Drift}} - \underbrace{\tau(\mathbf{v} \cdot \partial_{\mathbf{r}}) f}_{\text{Diffusion}}$

By definition, the charge current reads  $\mathbf{J}_c = -2e \int \frac{d^3 p}{(2\pi)^3} \mathbf{v} \delta f$

Drift-diffusion equation

$$\boxed{\begin{aligned} \mathbf{J}_c &= \sigma_c \mathbf{E} - D_c \partial_{\mathbf{r}} n \\ \partial_t n + \nabla \cdot \mathbf{J}_c &= 0 \end{aligned}}$$

Conductivity  $\sigma_c = \frac{1}{3} \tau e^2 v_F^2 \mathcal{N}(\varepsilon_F)$

Einstein relation

Diffusion coefficient  $D_c = \frac{1}{3} \tau v_F^2$

$$\sigma_c = e^2 \mathcal{N}(\varepsilon_F) D_c$$

## a. Semi-classical charge transport

A few words on the collision integral

$$\frac{df}{dt} \Big|_{\text{coll}} = \frac{1}{\Omega} \int \frac{d^3 p'}{(2\pi)^3} W_{vv'} (f_{v'} - f_v)$$

### Scattering against impurities

$$V_{imp} \approx \sum_i V_0 \delta(\mathbf{r} - \mathbf{R}_i)$$

In the limit of short-range impurities, the momentum relaxation time is independent of the momentum

$$\frac{1}{\tau} = n_i |V_0|^2 \mathcal{N}(\varepsilon_F)$$

Impurity concentration

Constant relaxation time approximation

### Scattering against phonons

$$V_{e-ph} = \sum_i V(r - R_i - \delta R_i(t))$$

It can be written in second quantization

$$V_{e-ph} = \sum_{\mathbf{k}, \mathbf{q}} (B_{\mathbf{q}} c_{\mathbf{k}+\mathbf{q}}^\dagger c_{\mathbf{k}} b_{\mathbf{q}} + B_{-\mathbf{q}} c_{\mathbf{k}-\mathbf{q}}^\dagger c_{\mathbf{k}} b_{\mathbf{q}}^\dagger)$$

Phonon absorption

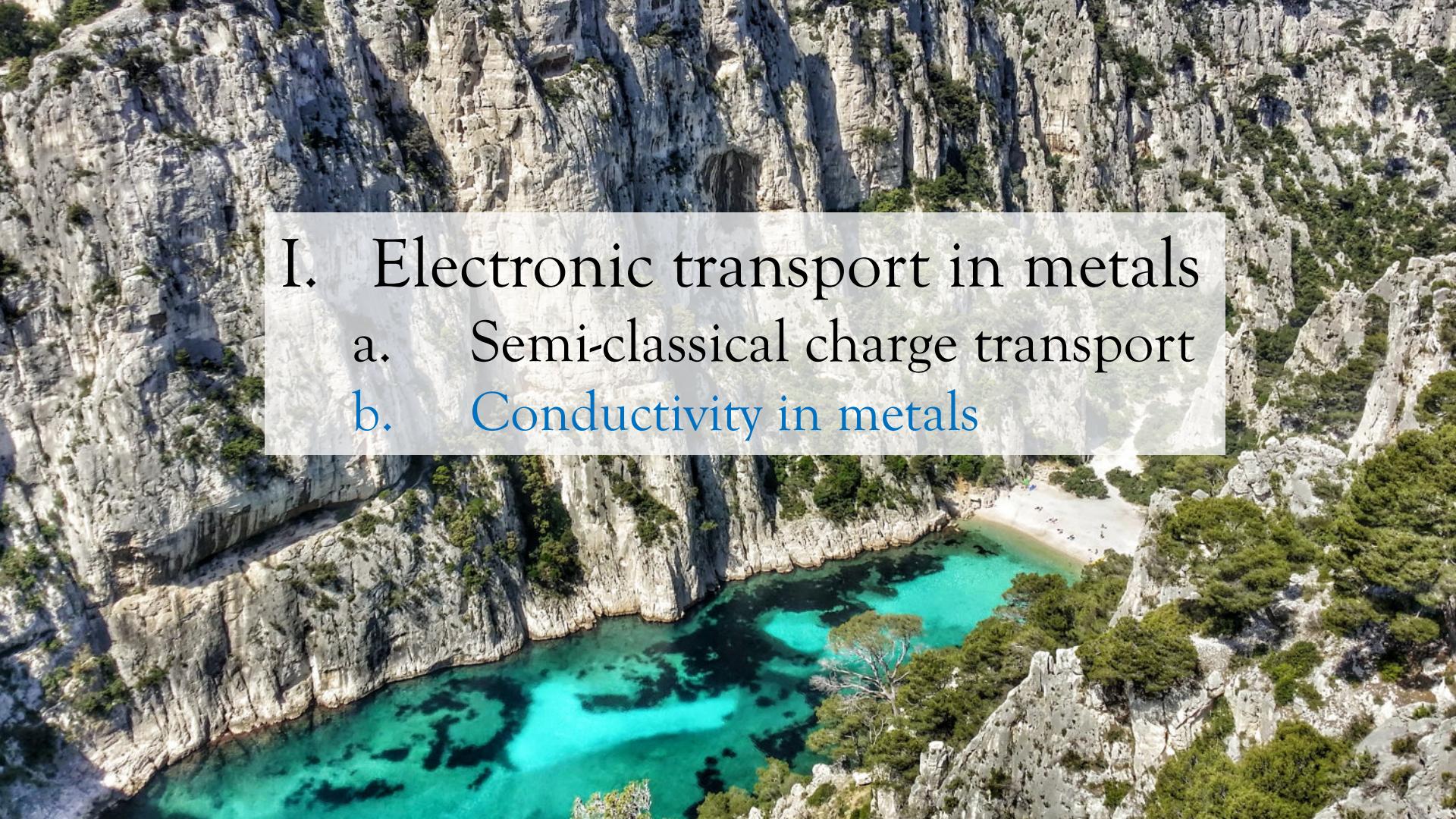
Phonon emission

$$\frac{1}{\tau} \sim T^5, T \ll \Theta$$

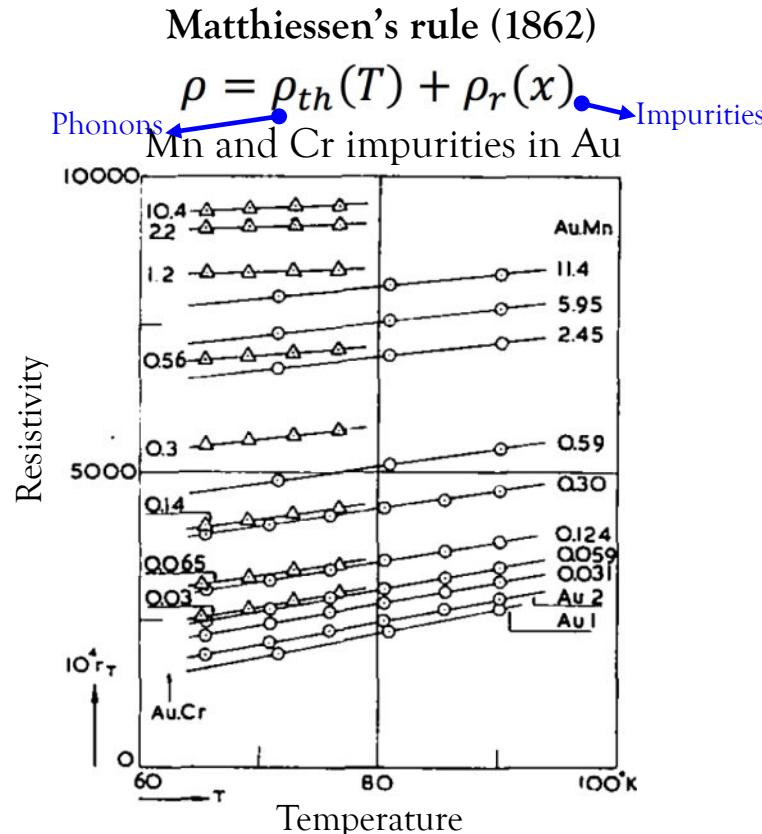
Debye temperature

$$\frac{1}{\tau} \sim T, T \gg \Theta$$

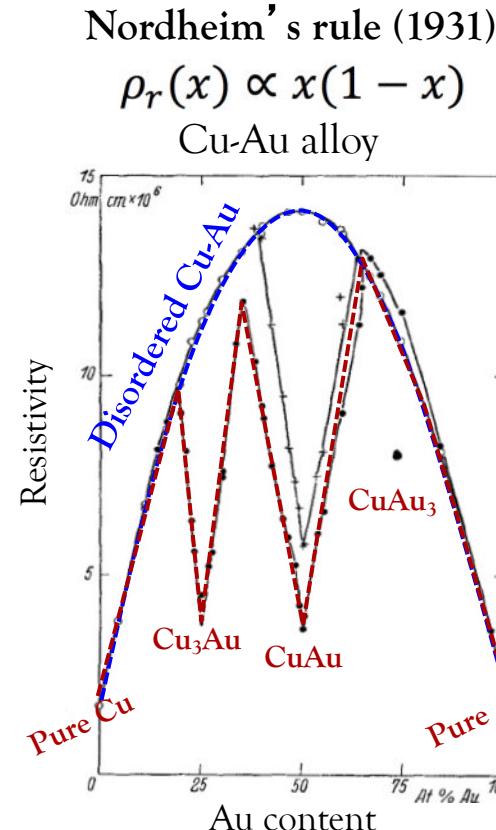
The scattering time increases with temperature

- 
- I. Electronic transport in metals
- a. Semi-classical charge transport
  - b. **Conductivity in metals**

## b. Conductivity of metals



Gerritsen and Linde, Physica 18, 877 (1952)



Johansson and Linde, Annal der Physics 5, 1 (1936)

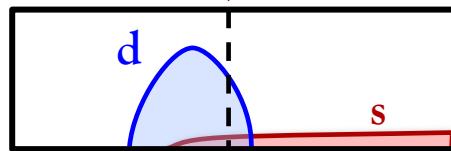
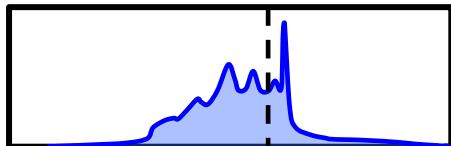
## b. Conductivity of transition metals



Nevill F. Mott

### The s-d model in transition metals (Mott 1935)

Typical density of states of a transition metal

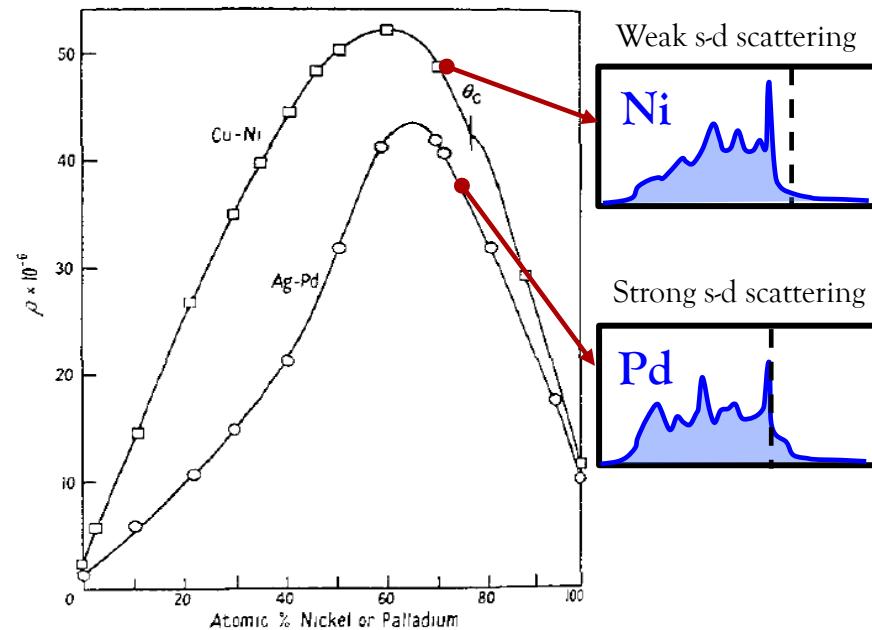


$$v_s \gg v_d$$
$$\mathcal{N}_d(\epsilon_F) \gg \mathcal{N}_s(\epsilon_F)$$

Transport is dominated by s-electrons  
But...s-d scattering is quite strong!

$$\frac{1}{\tau_s} = \frac{1}{\tau_{ss}} + \frac{1}{\tau_{sd}}$$

Deviation from Nordheim's rule



Coles, Proc. Phys. Soc. B 65 221 (1952)

## b. Conductivity of transition metals

### Conductivity enhancement in magnetic transition metals

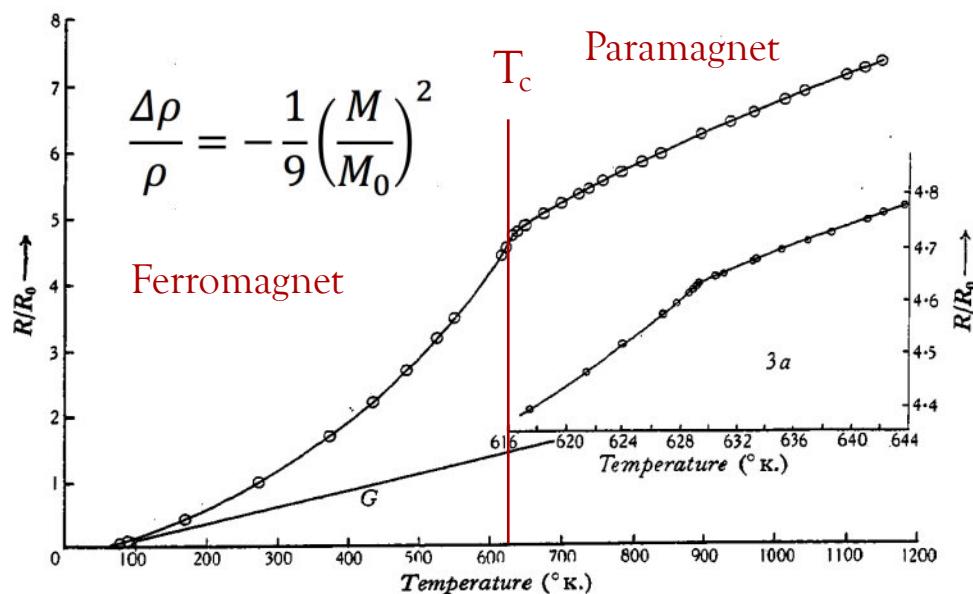


Figure 3. Resistance of nickel as a function of temperature.

Figure 3a. The neighbourhood of the Curie point.

We remember that  $\sigma_c \sim \mathcal{N}(\varepsilon_F)$

In a free electron model

$$\mathcal{N}_\sigma(\varepsilon_F) \sim \sqrt{\varepsilon_F} \sim (n_F^\sigma)^{1/3}$$

One can define

$$P = \frac{n_F^\uparrow - n_F^\downarrow}{n_F^\uparrow + n_F^\downarrow} \Rightarrow n_F^{\uparrow,\downarrow} = \bar{n}_F(1 \pm P)$$

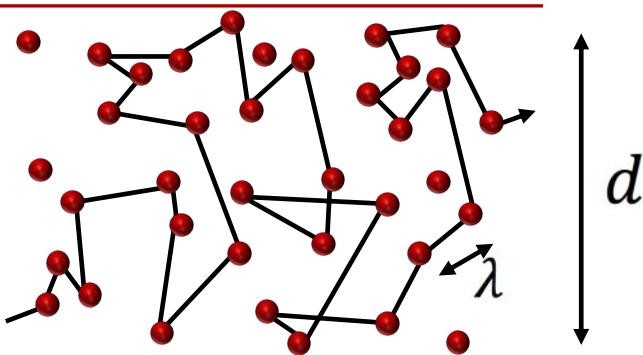
Spin polarization at Fermi level

Assuming  $P \approx \frac{M(T)}{M_0}$  we get

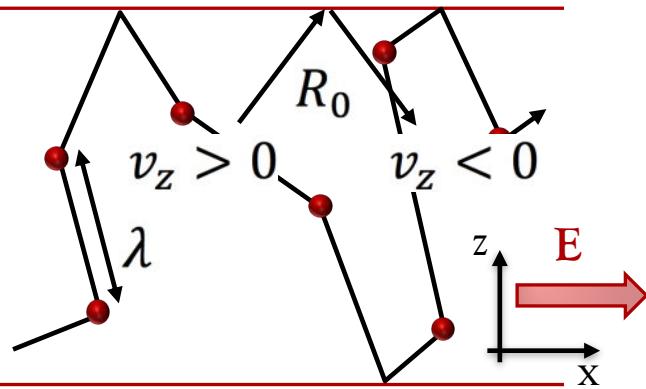
$$\rho = \rho_{ss} + \frac{\rho_{sd}}{2} \left( \left( 1 - \frac{M}{M_0} \right)^{1/3} + \left( 1 + \frac{M}{M_0} \right)^{1/3} \right)$$

# Size effect in thin films: Fuchs-Sondheimer theory

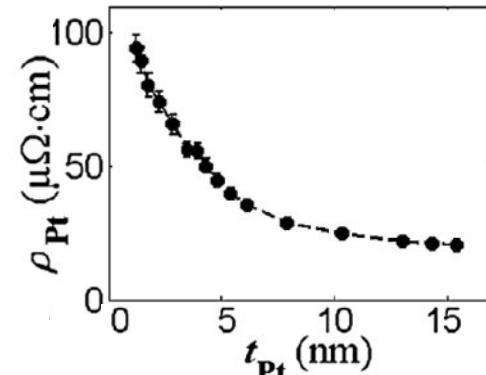
Diffusive regime  $\lambda \ll d$



Knudsen regime  $\lambda \sim d$

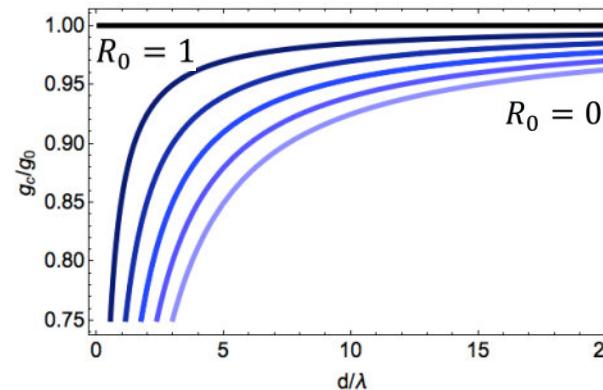


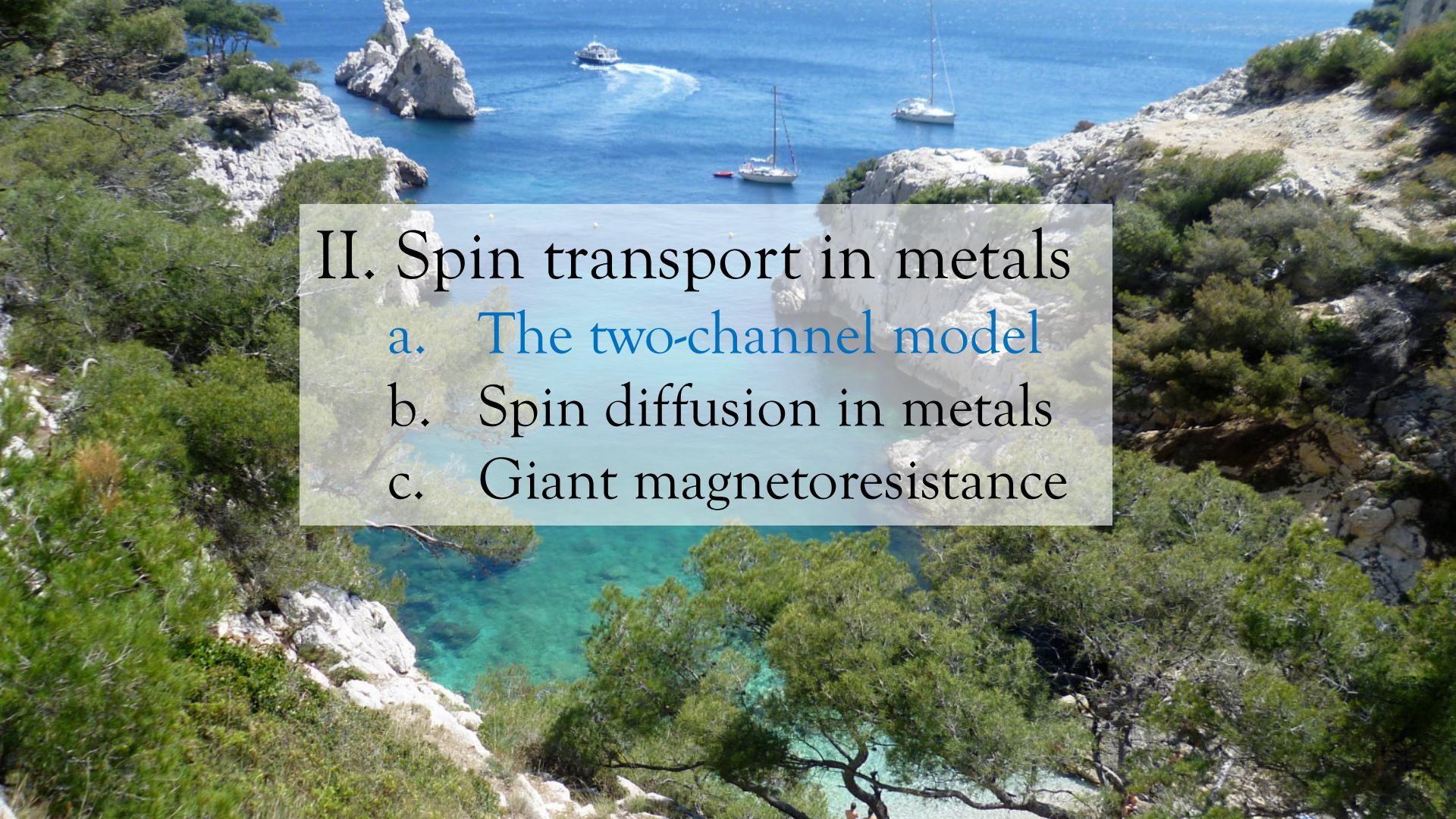
Resistivity of Pt thin film



Nguyen et al., Physical Review Letters 116, 126601 (2016)

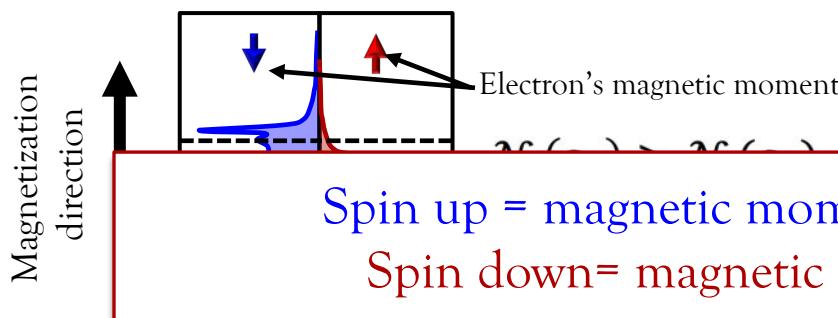
Total conductivity



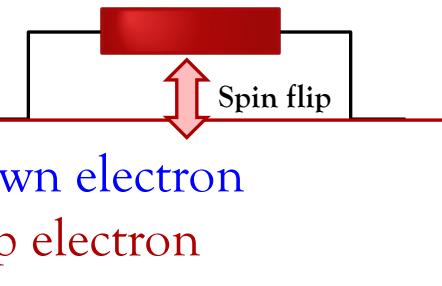
- 
- II. Spin transport in metals
- a. The two-channel model
  - b. Spin diffusion in metals
  - c. Giant magnetoresistance

# The two-channel model

Density of states in a ferromagnet



Equivalent circuit



Spin dependent scattering

$$\frac{1}{\tau_{\downarrow}} > \frac{1}{\tau_{\uparrow}}, \lambda_{\uparrow} > \lambda_{\downarrow}$$

Spin-dependent mean free path

Spin relaxation

$$\lambda_{sf}^{\sigma} = \sqrt{\frac{1}{3} v_{\sigma} \lambda_{\sigma} \tau_{\uparrow\downarrow}}$$

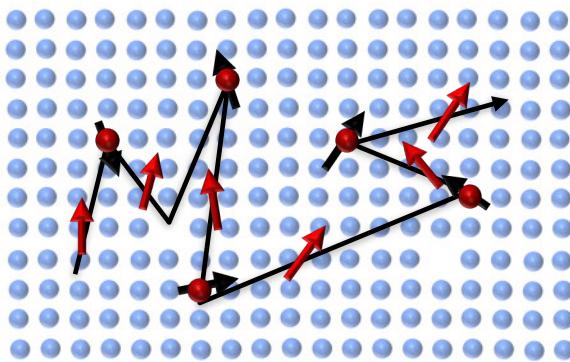
Spin relaxation time

Spin relaxation length  
Spin diffusion length

$$\frac{1}{\lambda_{sf}} = \frac{1}{\sqrt{(\lambda_{sf}^{\uparrow})^2 + (\lambda_{sf}^{\downarrow})^2}}$$

# Spin relaxation

## Magnetic impurities

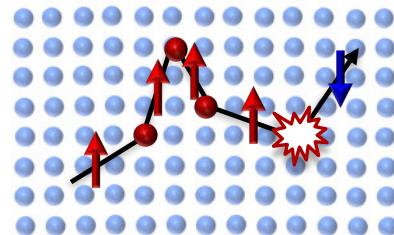


Isolated magnetic impurities acts like a random field, spatially distributed

$$\frac{1}{\tau_{sf}^m} = \frac{8\pi}{3} n_m N_0 S(S+1) v_{sm}^2$$

The stronger the scattering,  
the faster the spin relaxation

## Elliott-Yafet scattering



The itinerant spin precesses around the spin-orbit field

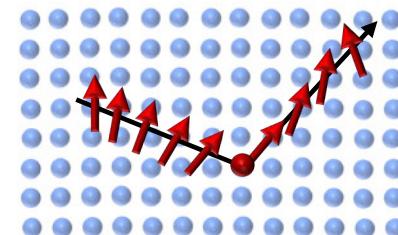
$$H_{so} = \xi_{so} \boldsymbol{\sigma} \cdot \mathbf{L} \propto \xi_{so} \boldsymbol{\sigma} \cdot (\mathbf{k} \times \mathbf{k}')$$

The precession occurs upon scattering  
(phonons or impurities)

$$\frac{1}{\tau_{sf}^{so}} = \frac{8\xi_{so}^2}{9} \frac{1}{\tau}$$

The fast the scattering,  
the faster the spin relaxation

## Dyakonov-Perel' relaxation



The itinerant spin precesses **continuously** around the spin-orbit field of the **crystal**

$$H_R = -\alpha \boldsymbol{\sigma} \cdot (\mathbf{z} \times \mathbf{k})$$

The precession occurs **during** propagation

It leads to anisotropic relaxation times

$$\frac{1}{\tau_{sf}^{R,||}} = \frac{2\alpha^2 k_F^2}{\hbar^2} \tau \quad \frac{1}{\tau_{sf}^{R,z}} = \frac{4\alpha^2 k_F^2}{\hbar^2} \tau$$

The fast the scattering,  
the slower the spin relaxation

# The two-channel model

We start from Boltzmann transport equation

$$\int \frac{d^3 p}{(2\pi)^3} \quad v \times$$

$$-(e\mathbf{E} \cdot \mathbf{v}) \partial_{\varepsilon} f = -\frac{f_{\downarrow} - f_0}{\tau_{\downarrow}} + \frac{f_{\uparrow} - f_{\downarrow}}{\tau_{\uparrow\downarrow}}$$

$$-(e\mathbf{E} \cdot \mathbf{v}) \partial_{\varepsilon} f = -\frac{f_{\uparrow} - f_0}{\tau_{\uparrow}} - \frac{f_{\uparrow} - f_{\downarrow}}{\tau_{\uparrow\downarrow}}$$

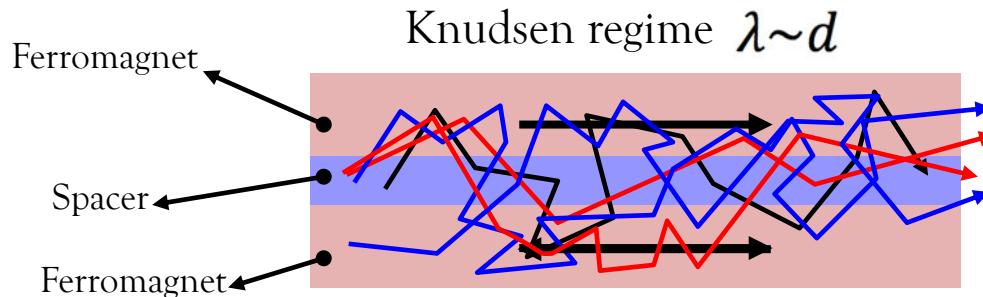
Weak spin relaxation: decoupled spin channels

$$\frac{1}{\tau_{\uparrow}}, \frac{1}{\tau_{\downarrow}} \gg \frac{1}{\tau_{\uparrow\downarrow}} \Rightarrow \begin{cases} \sigma_{\downarrow} = \tau_{\downarrow} \frac{e^2 v_F^2}{3} \mathcal{N}(\varepsilon_F) \\ \sigma_{\uparrow} = \tau_{\uparrow} \frac{e^2 v_F^2}{3} \mathcal{N}(\varepsilon_F) \end{cases}$$

Strong spin relaxation: no spin-dependence

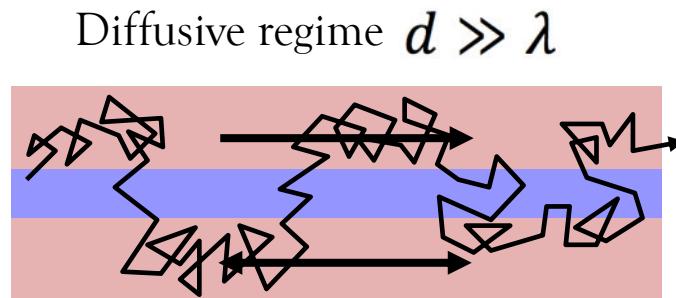
$$\frac{1}{\tau_{\uparrow\downarrow}} \gg \frac{1}{\tau_{\uparrow}}, \frac{1}{\tau_{\downarrow}} \Rightarrow \begin{cases} \sigma_{\downarrow} = \frac{2\tau_{\uparrow}\tau_{\downarrow}}{(\tau_{\uparrow} + \tau_{\downarrow})} \frac{e^2 v_F^2}{3} \mathcal{N}(\varepsilon_F) \\ \sigma_{\uparrow} = \frac{2\tau_{\uparrow}\tau_{\downarrow}}{(\tau_{\uparrow} + \tau_{\downarrow})} \frac{e^2 v_F^2}{3} \mathcal{N}(\varepsilon_F) \end{cases}$$

# Current-in-plane Giant Magnetoresistance

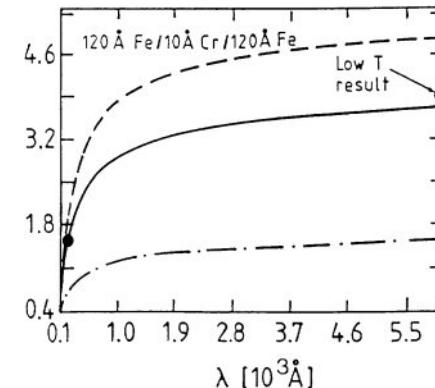


Parallel  $\sigma_c^{\uparrow} > \sigma_c^{\downarrow}$

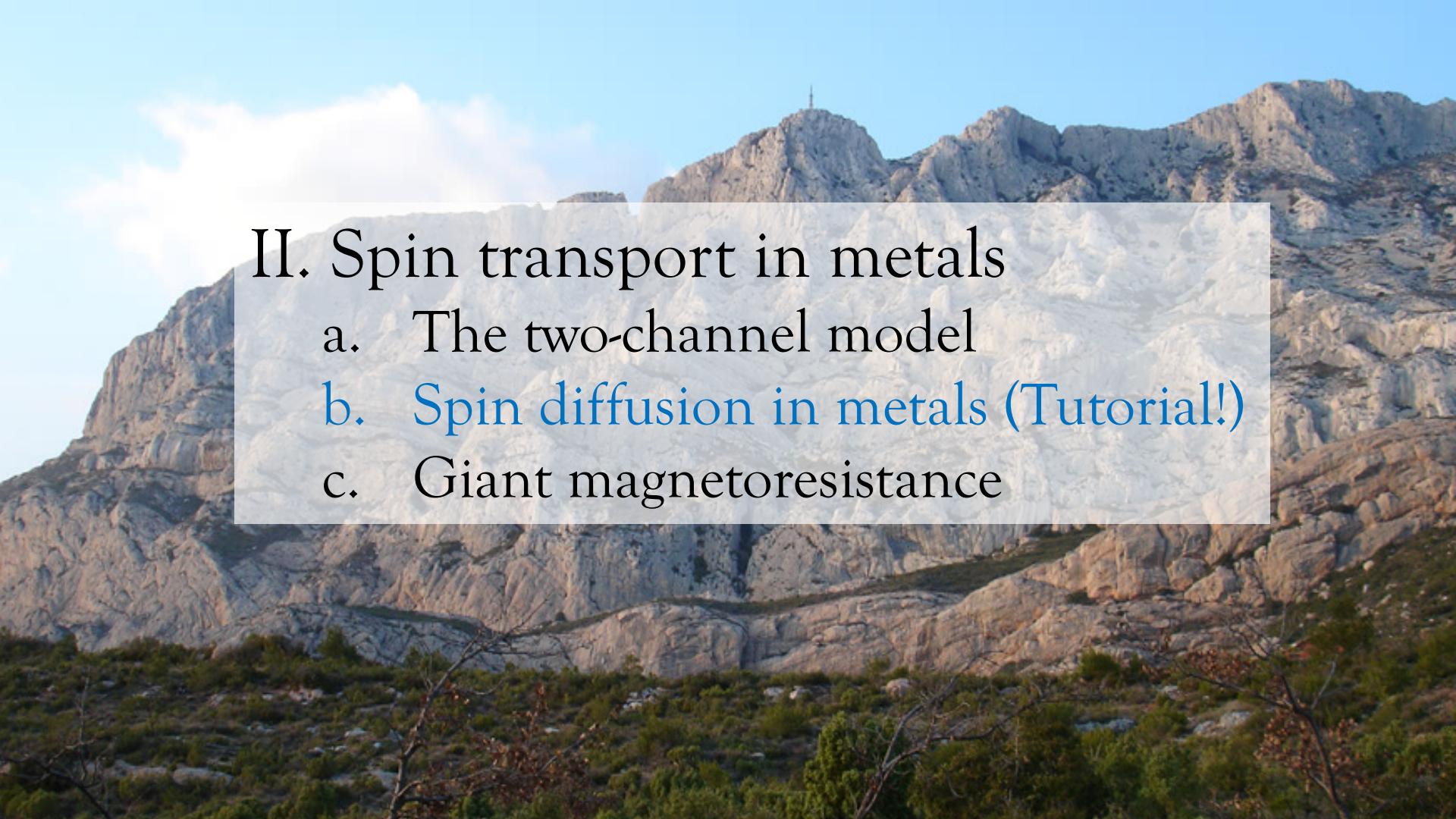
Antiparallel  $\sigma_c^{\uparrow} \sim \sigma_c^{\downarrow}$



The electron doesn't “remember”  
where it comes from!



Camley, Physical Review Letters 63, 664 (1989)

- 
- II. Spin transport in metals
- a. The two-channel model
  - b. Spin diffusion in metals (Tutorial!)
  - c. Giant magnetoresistance

# Spin transport in metals

Remember that in a metal, charge transport is governed by

Charge current density     $\mathbf{J}_c = \sigma_c(\mathbf{E} - \nabla\mu)_l$     Flow of charge per unit area

Charge density         $\partial_t n + \nabla \cdot \mathbf{J}_c = 0$         Number of charge per unit volume

Chemical potential     $\mu = \frac{n}{e\mathcal{N}(\varepsilon_F)}$

Total charge density     $n = n_\uparrow + n_\downarrow$   
(C/m<sup>3</sup>)

$$\bar{\mu} = \frac{1}{2}(\mu_\uparrow + \mu_\downarrow)$$

Spin-independent  
chemical potential

Total spin density     $s = \left(\frac{\hbar}{2e}\right)(n_\uparrow - n_\downarrow)$   
((eV.s)/m<sup>3</sup>)

$$\mu_s = \frac{1}{2}(\mu_\uparrow - \mu_\downarrow)$$

Spin-dependent  
chemical potential

Magnetic moment     $m = -\left(\frac{\mu_B}{e}\right)(n_\uparrow - n_\downarrow)$   
(μ<sub>B</sub>/m<sup>3</sup>)

# Spin diffusion equation

Charge current

$$\mathbf{J}_c = \sigma_c(\mathbf{E} - \nabla\mu)$$

Charge conservation

$$\partial_t n + \nabla \cdot \mathbf{J}_c = 0$$

Ohm's law

$$J_c = g(\mu_R - \mu_L)$$

Chemical potential

$$\mu = \frac{n}{eN(\varepsilon_F)}$$

$$\mathbf{J}_c^\sigma = \sigma_c^\sigma(\mathbf{E} - \nabla\mu_\sigma)$$

$$\partial_t n_\sigma + \nabla \cdot \mathbf{J}_c^\sigma = 0$$

$$J_c^\sigma = g_\sigma(\mu_R^\sigma - \mu_L^\sigma)$$

$$\mu_\sigma = \frac{n_\sigma}{eN(\varepsilon_F)}$$

Valet and Fert, Physical Review B 48, 7099 (1993)

Charge and spin current definitions

$$\begin{aligned} \mathbf{J}_c &= \mathbf{J}_c = \sigma_c(\mathbf{E} - \nabla\bar{\mu}) - \beta\sigma_c\nabla\mu_s^\uparrow \quad \nabla\mu_s^\downarrow \\ \frac{2e}{\hbar}\mathbf{J}_s &= \frac{2e}{\hbar}\mathbf{J}_s = \beta\sigma_c(\mathbf{E} - \nabla\bar{\mu}) - \sigma_c\nabla\mu_s^\downarrow \quad \nabla\mu_s^\uparrow \end{aligned}$$

Total conductivity

$$\sigma_c = \sigma_c^\uparrow + \sigma_c^\downarrow$$

Current polarization

$$\beta = \frac{\sigma_c^\uparrow - \sigma_c^\downarrow}{\sigma_c^\uparrow + \sigma_c^\downarrow}$$

Charge and spin conservation

$$\partial_t n + \nabla \cdot \mathbf{J}_c = 0$$

$$\partial_t s + \nabla \cdot \mathbf{J}_s = -\frac{s}{\tau_{sf}}$$

In steady state

$$\frac{2e}{\hbar\sigma_c} \nabla \cdot \mathbf{J}_s \approx -\frac{\mu_s}{\lambda_{sf}^2}$$

$$\lambda_{sf}^2 = D_c \tau_{sf}$$

Spin relaxation

# Spin accumulation

The concept of spin accumulation

$$\left. \begin{array}{l} \text{Charge} \\ \text{Spin} \end{array} \right\} \begin{aligned} J_c &= \sigma_c(E - \nabla \bar{\mu}) - \beta \sigma_c \nabla \mu_s \\ \nabla \cdot J_c &= 0 \\ J_s &= \beta \sigma_c(E - \nabla \bar{\mu}) - \sigma_c \nabla \mu_s \\ \frac{1}{\sigma_c} \nabla \cdot J_s &= -\frac{\mu_s}{\lambda_{sf}^2} \end{aligned}$$



$$\begin{aligned} \bar{\mu} &= -\beta \mu_s + Ax + B \\ \mu_s &= Ce^{x/\lambda_{sf}^*} + De^{-x/\lambda_{sf}^*} \\ \lambda_{sf}^{*2} &= (1 - \beta^2) \lambda_{sf}^2 \end{aligned}$$

Spin accumulation

Spin accumulation profile

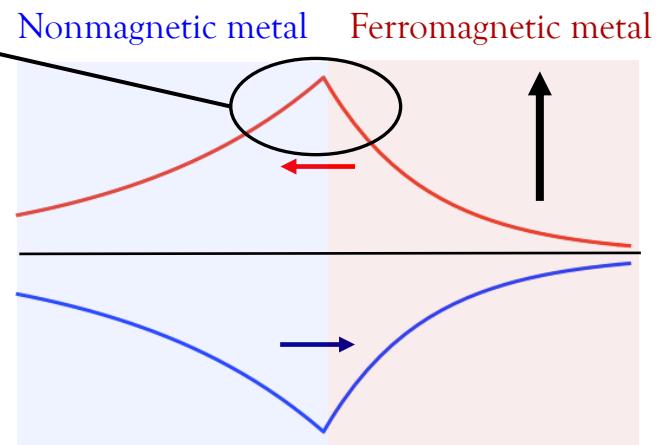
$$\mu_{s,N}(x) = -J_c \frac{\beta e^{x/\lambda_F}}{\sigma_F \beta > 0, \lambda_{sf}^* = \lambda_F} = -J_c \frac{\beta e^{-x/\lambda_F}}{\sigma_F + \sigma_N}$$

Interfacial Matching Conditions

Spin density ~~continuous~~  $\rightarrow$  no interfacial resistance  
Spin current ~~continuous~~  $\rightarrow$  no spin flip

$$\frac{\Delta \mu}{J_c} = \frac{\beta}{\frac{\sigma_F}{\lambda_F} + \frac{\sigma_N}{\lambda_N}}$$

Additional interfacial resistance!!



van Son et al., Physical Review Letters 58, 2271 (1987)  
Johnson and Silsbee, Physical Review B 35, 4959 (1987)

# Spin current

Ohm's law

$$J_c = g_I \Delta \mu \quad \rightarrow \quad J_c = g_I \Delta \bar{\mu} + \gamma g_I \Delta \mu_s$$

$$J_s = \gamma g_I \Delta \bar{\mu} + g_I \Delta \mu_s$$

The spin current in the ferromagnet reads

$$\frac{J_{s,F}}{J_c} = \beta - \frac{(\beta - \gamma)r_I + \beta r_N^s}{r_I + r_F^s + r_N^s} e^{-x/\lambda_F^*}$$

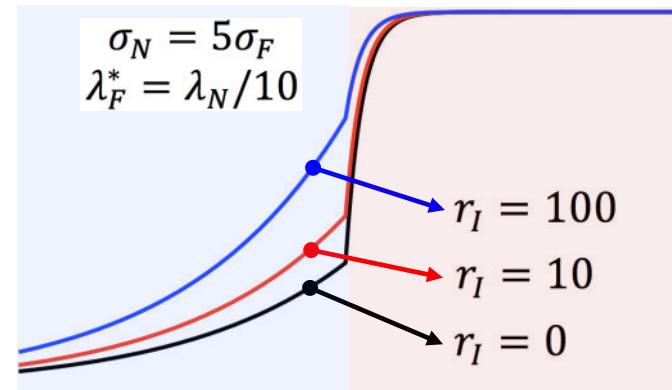
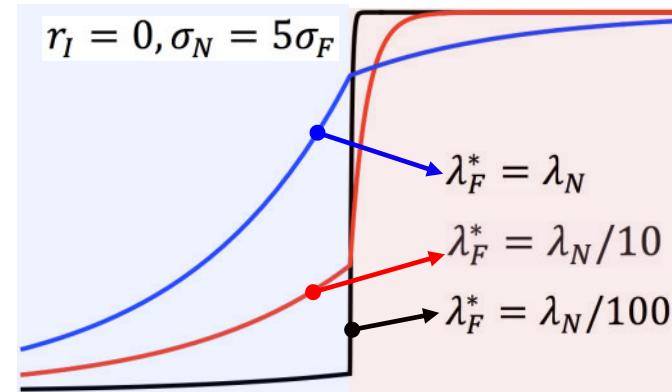
Spin diffusion length  
of the ferromagnet

Interfacial resistance  $r_I = (1 - \gamma^2)/g_I$

"spin" resistance  $r_N^s = \frac{\lambda_N}{\sigma_N}, r_F^s = \frac{\lambda_F}{\sigma_F}$

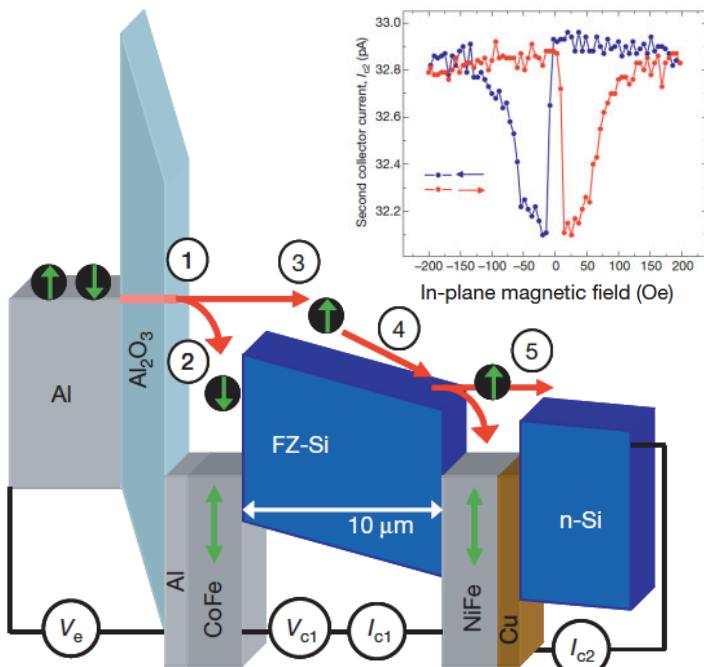
The **shorter** the spin diffusion length,  
the **smaller** the spin resistance

Nonmagnetic metal      Ferromagnetic metal

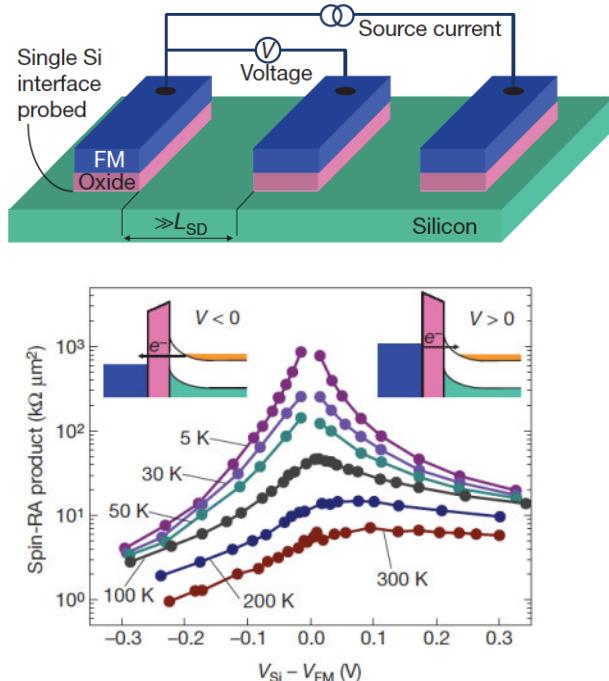


# Spin injection

Appelbaum et al., Nature 447, 295 (2007)  
Hot electron injection



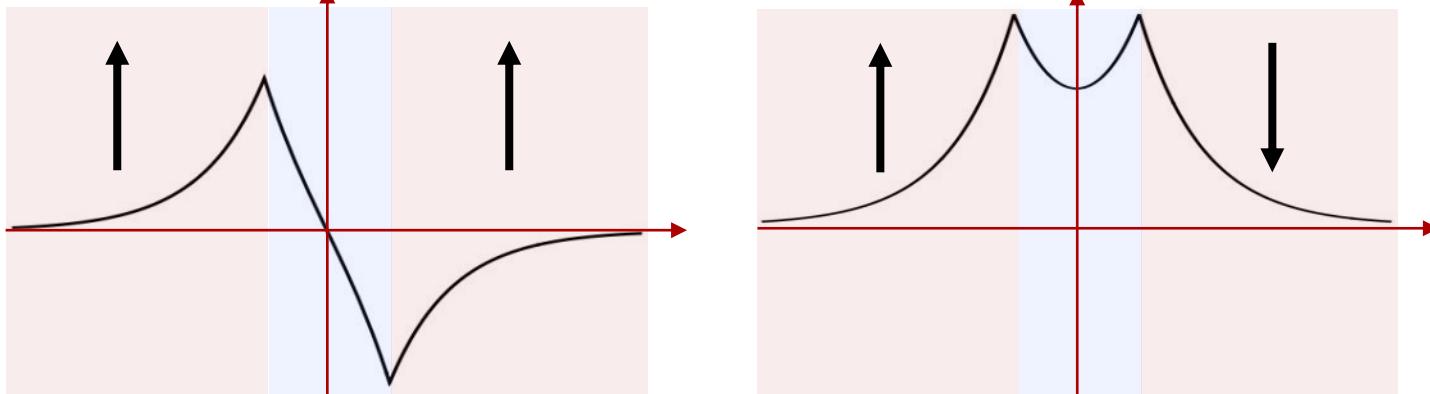
Dash et al., Nature 462, 491 (2009)  
Non-local tunneling injection



- 
- II. Spin transport in metals
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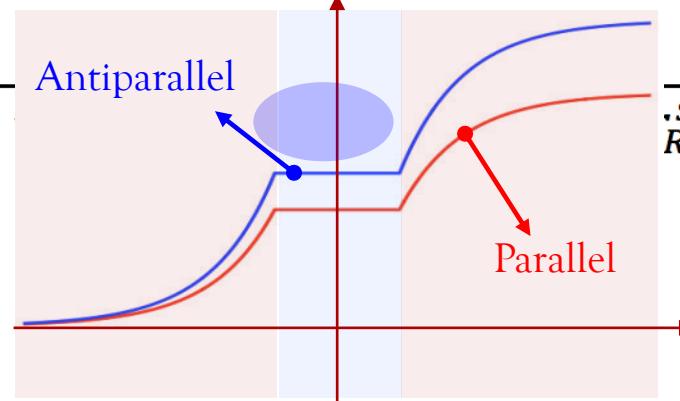
# Magnetoresistance

Spin accumulation profile in a metallic spin-valve



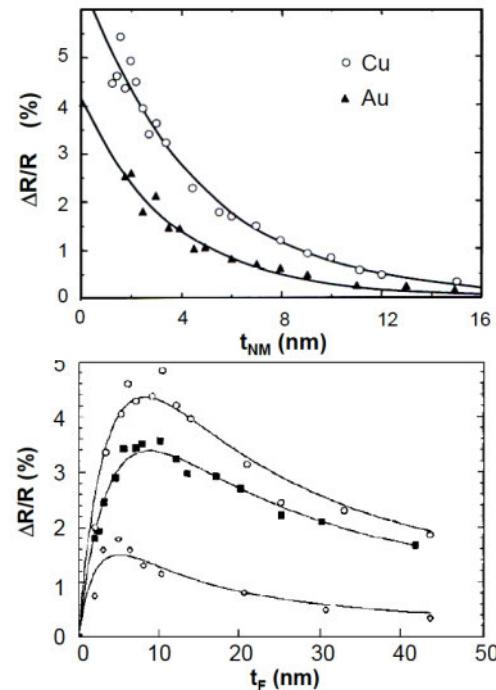
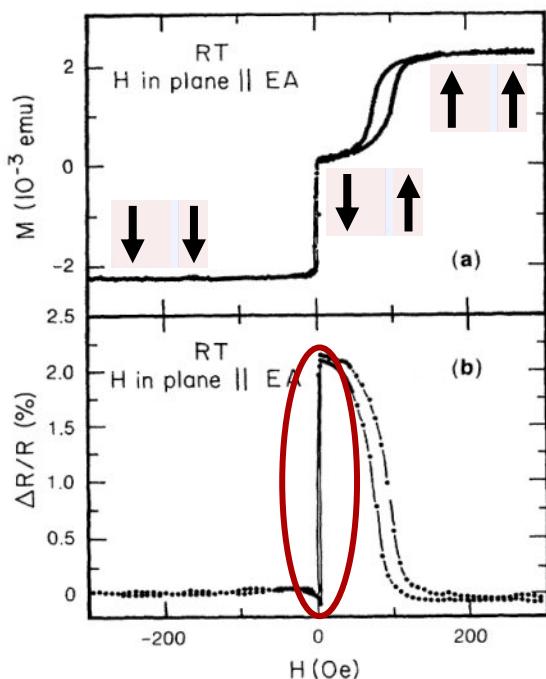
Chemical potential profile

$$r = \frac{\Delta r = \bar{\mu}_{-\infty} - \bar{\mu}_{+\infty}}{J_c} + \frac{s}{R} \cosh\left(\frac{d}{\lambda_{sf}}\right)$$



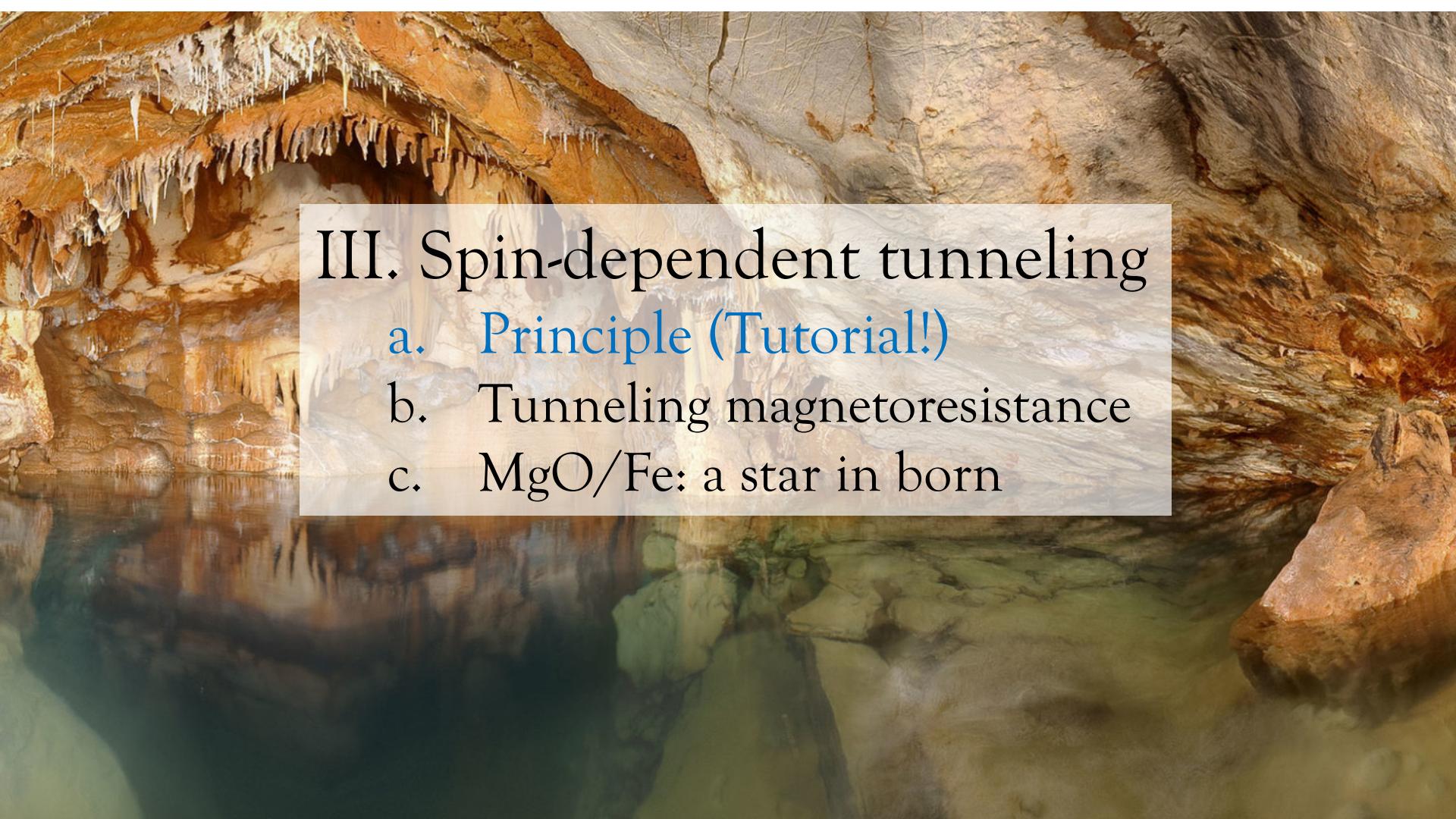
# Magnetoresistance

$$\Delta r = \frac{4\beta_L\beta_R r_L^s r_R^s r_N^s}{(r_N^{s2} + r_L^s r_R^s) \sinh(d/\lambda_{sf}) + r_N^s(r_L^s + r_R^s) \cosh(d/\lambda_{sf})}$$



Dieny et al., Physical Review B 43, 1297 (1991)

Dieny et al., Journal of Applied Physics 69, 4774 (1991)

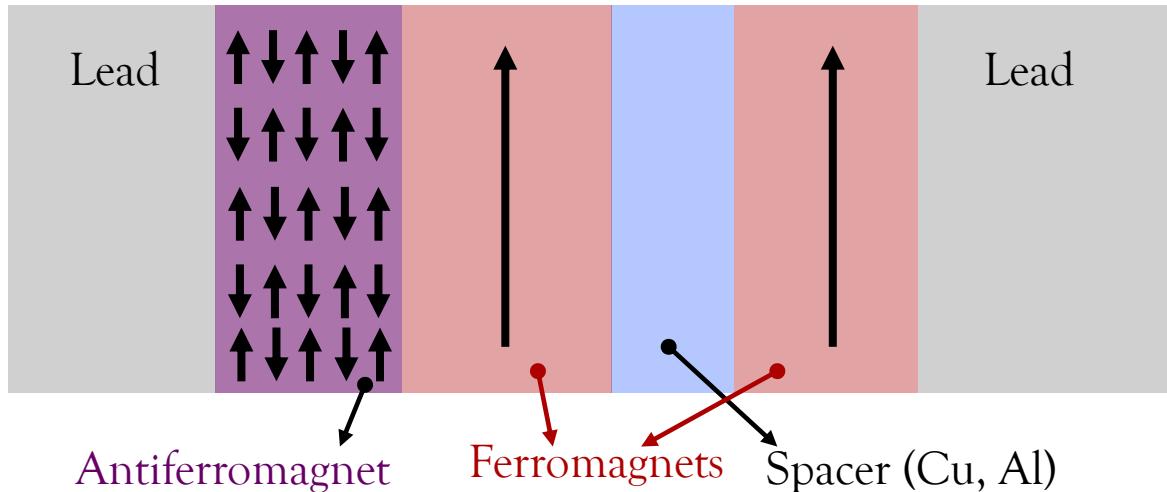


### III. Spin-dependent tunneling

- a. Principle (Tutorial!)
- b. Tunneling magnetoresistance
- c. MgO/Fe: a star is born

# Giant versus tunneling magnetoresistance

The problem with giant magnetoresistance



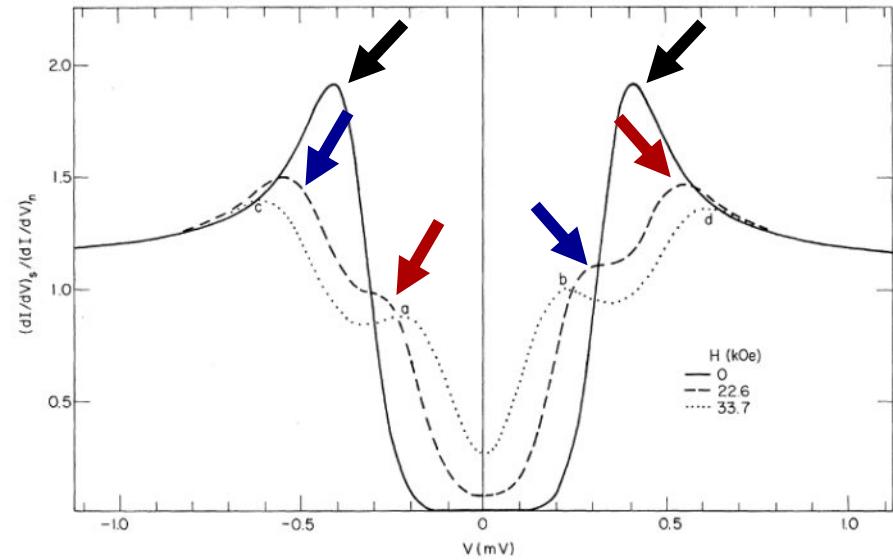
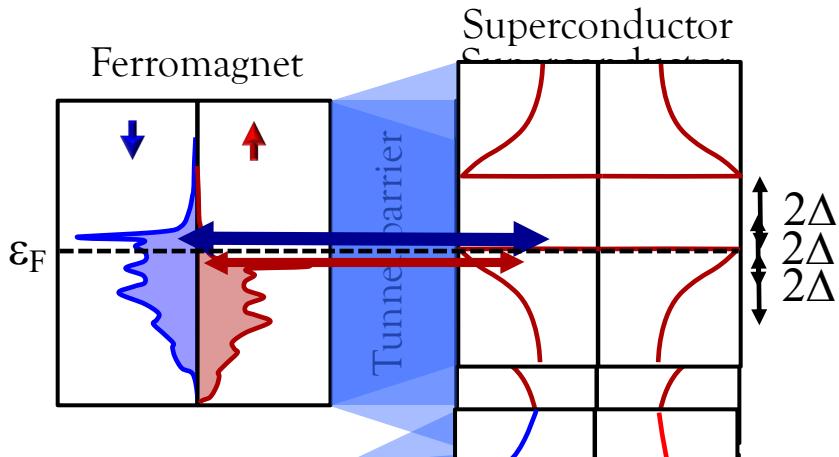
$$\Delta r \approx 4\beta_L\beta_R \frac{r_L^s r_R^s}{r_L^s + r_R^s}$$

The addition resistances in series quench the GMR ratio

$$\frac{\Delta r}{r} \sim \%$$

Solution: use a tunnel barrier!

# Spin-dependent tunneling



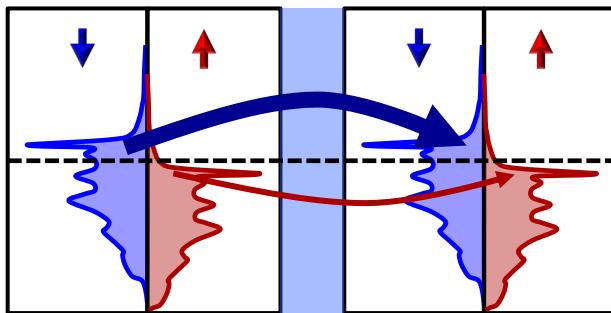
Tedrow and Meservey, Physical Review Letters 26, 192 (1971)

Al/Al<sub>2</sub>O<sub>3</sub>/Ni: P=29%  
Al/Al<sub>2</sub>O<sub>3</sub>/Co: P=38%  
Al/Al<sub>2</sub>O<sub>3</sub>/CoFe: P=48%

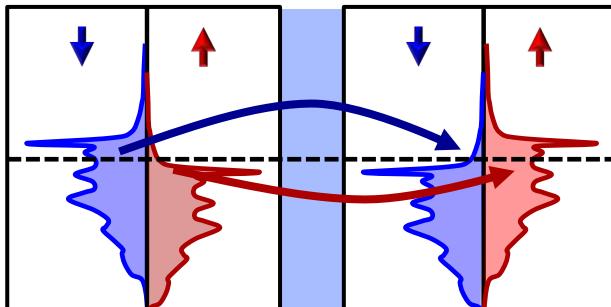
# Spin-dependent tunneling

## Basics of spin-dependent tunneling

Parallel configuration



Antiparallel configuration



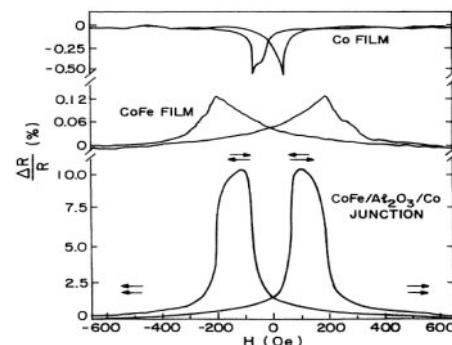
### In parallel configuration

The transport is dominated by electrons with **down electrons (up spin)**

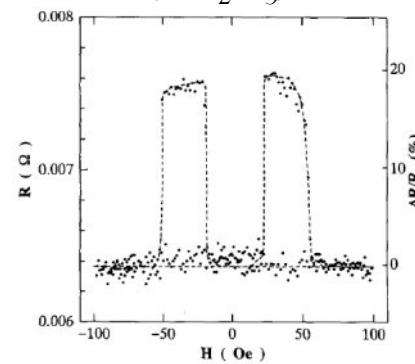
### In antiparallel configuration

Both **up and down electrons** contribute equally

CoFe/Al<sub>2</sub>O<sub>3</sub>/Co



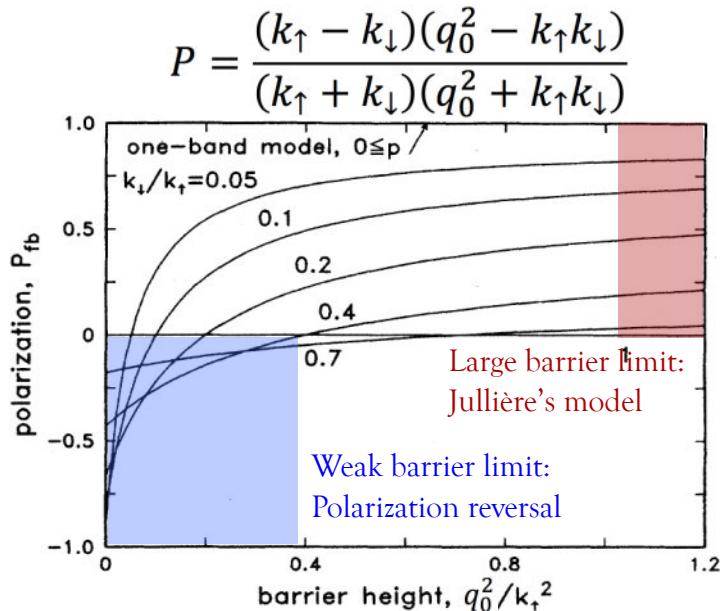
Fe/Al<sub>2</sub>O<sub>3</sub>/Fe



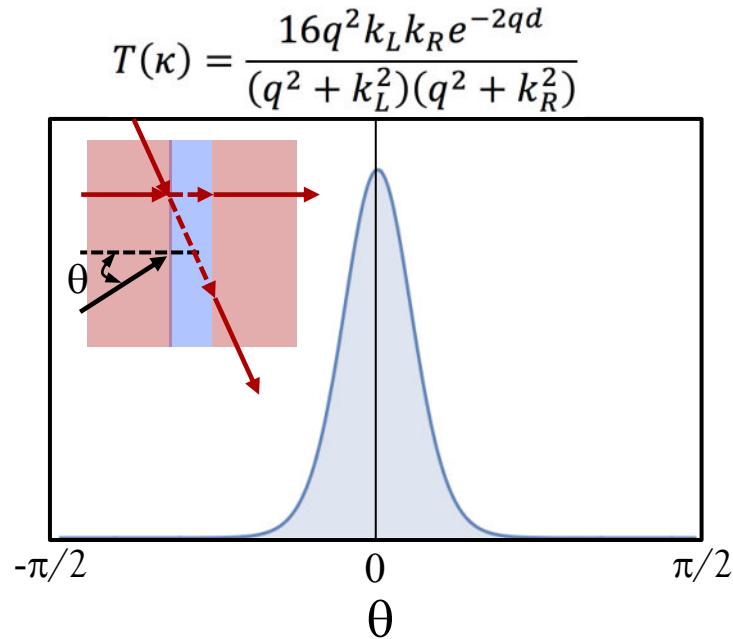
Moodera et al., Physical Review Letters 74, 3273 (1995)  
Miyazaki, Tezuka, JMMM 139, L231 (1995)

# Spin-dependent tunneling

Free electron model for spin-dependent tunneling



Slonczewski, Physical Review B 39, 6995 (1989)



$$U_{\text{MgO}} \approx 1 - 2 \text{ eV}, U_{\text{AlO}_x} \approx 3 \text{ eV}$$

$$k_F^{\uparrow} \approx 1.09 \text{ \AA}^{-1}, k_F^{\downarrow} \approx 0.42 \text{ \AA}^{-1}$$

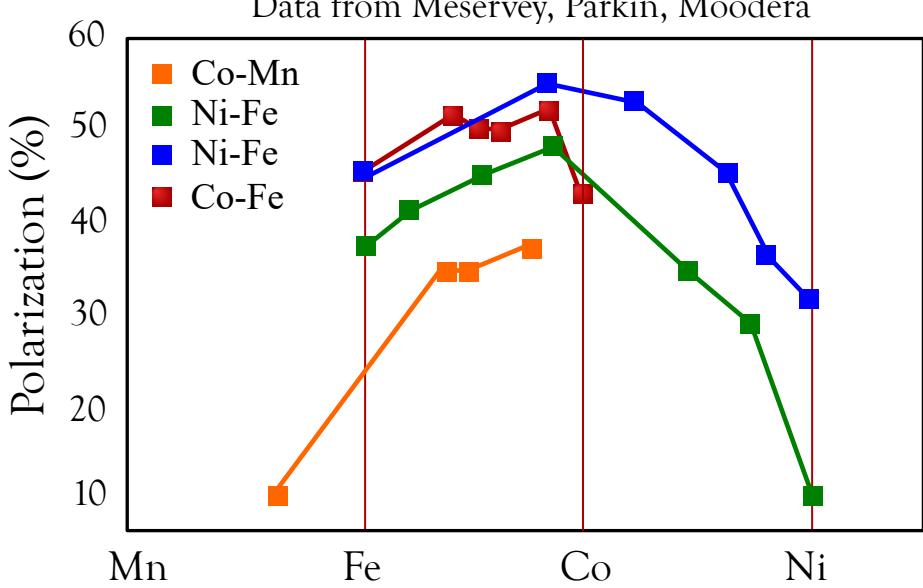
$$m^* \approx 0.4 m_e$$

# Spin-dependent tunneling

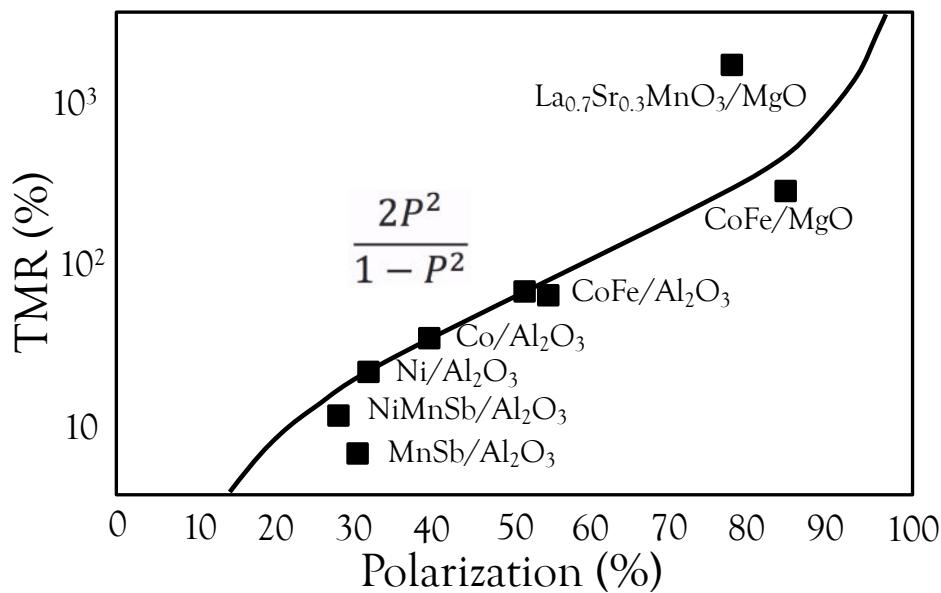
Jullière formula (see Tutorial!)

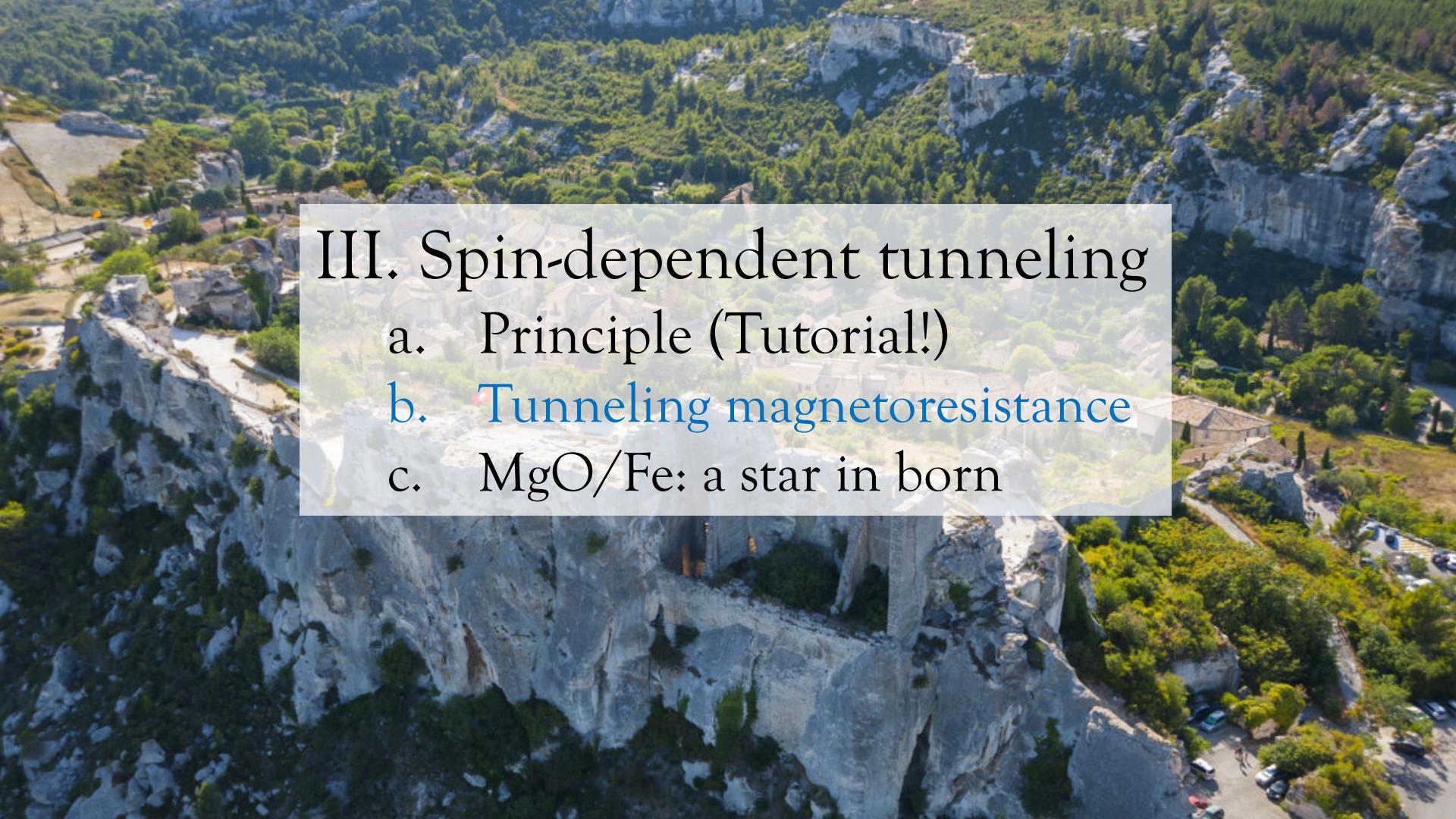
$$\frac{G_P - G_{AP}}{G_{AP}} = \frac{R_{AP} - R_P}{R_P} = \frac{2P_L P_R}{1 - P_L P_R}$$

Data from Meservey, Parkin, Moodera



Data collected by H. Swagten





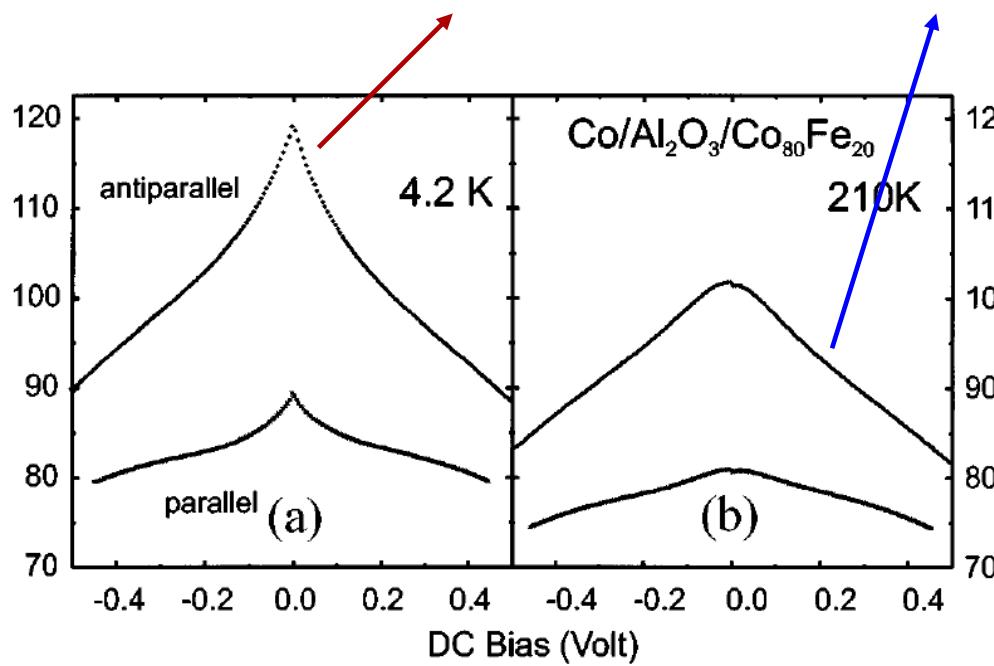
### III. Spin-dependent tunneling

- a. Principle (Tutorial!)
- b. [Tunneling magnetoresistance](#)
- c. MgO/Fe: a star is born

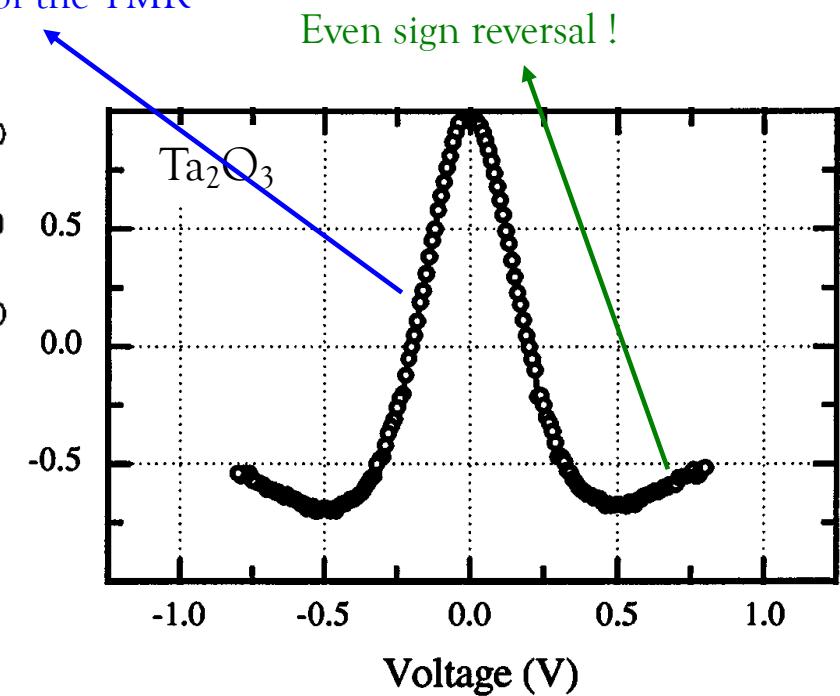
# Bias voltage of spin tunneling

Tunneling magnetoresistance has been studied with many barriers: AlO<sub>x</sub>, TaO<sub>x</sub>, MgO<sub>x</sub>, ZrO<sub>x</sub> etc.

Zero-bias anomalous at low T



Systematic decrease of the TMR

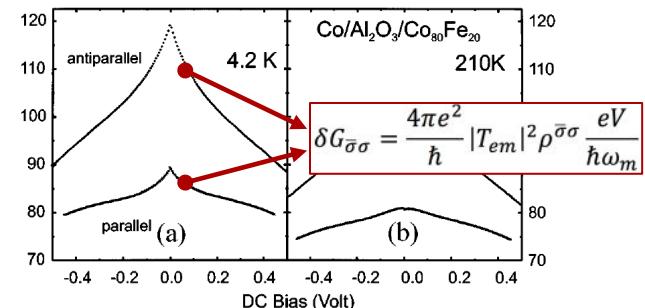
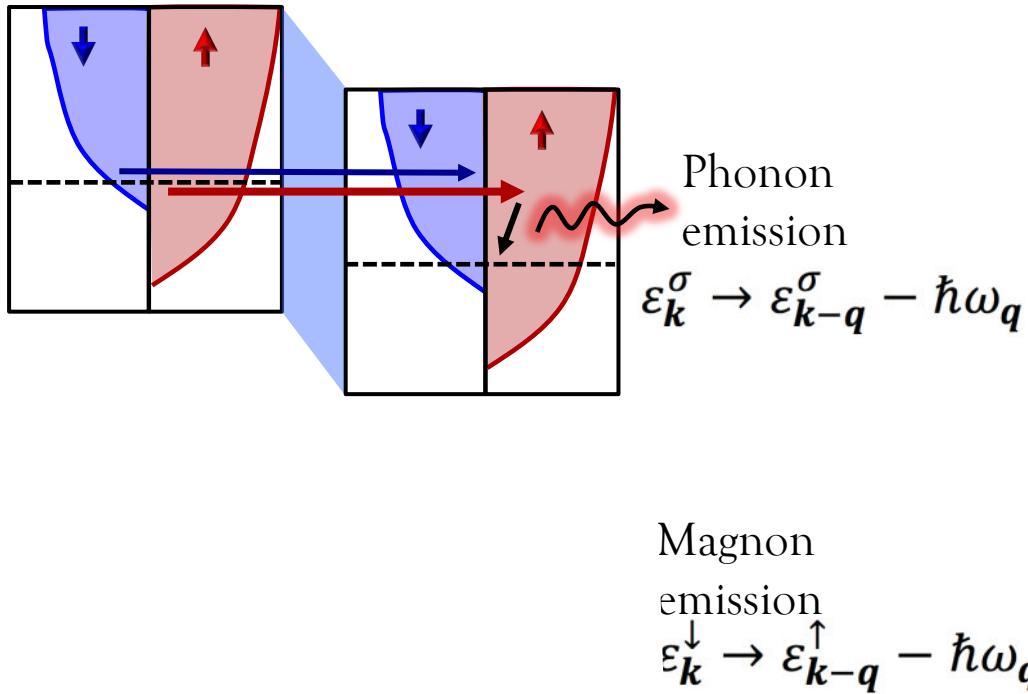


Zhang et al., Physical Review Letters 79, 3744 (1997)

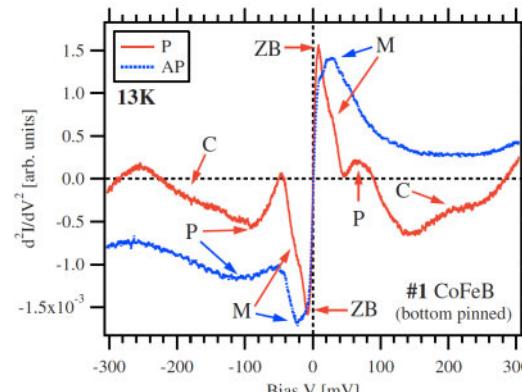
Sharma et al., Physical Review Letters 82, 616 (1999)

# Spin-dependent tunneling

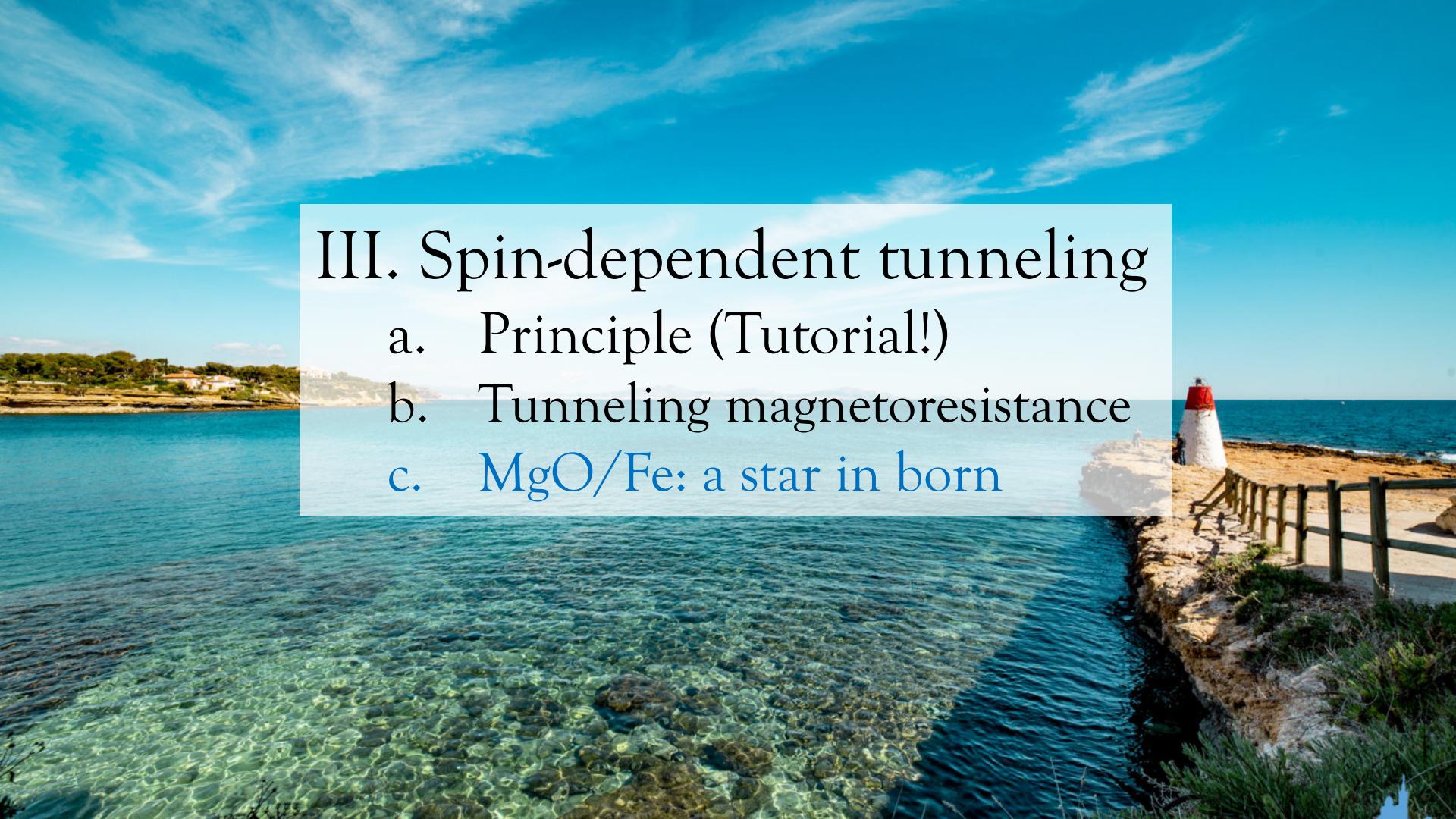
Hot electron tunneling: magnons and phonons



Zhang et al., Physical Review Letters 79, 3744 (1997)



Drewello et al., Physical Review B 79, 174417 (2009)



### III. Spin-dependent tunneling

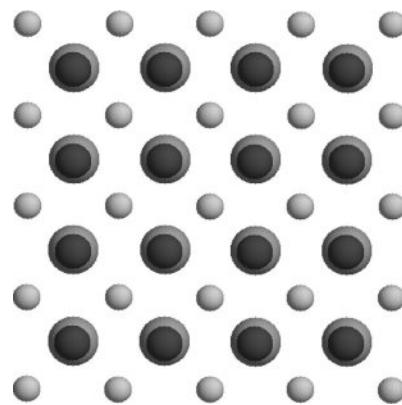
- a. Principle (Tutorial!)
- b. Tunneling magnetoresistance
- c. MgO/Fe: a star in born

# MgO/Fe interfaces

Why shall we expect remarkable tunneling magnetoresistance?

## Crystal structure

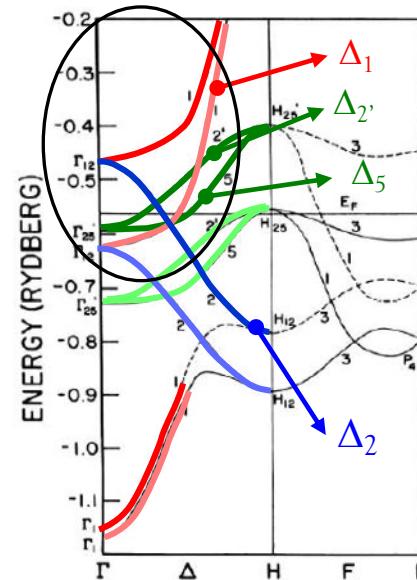
Fe and MgO have both bcc structure with very small lattice mismatch



Butler, Physical Review B 63, 054416 (2001)

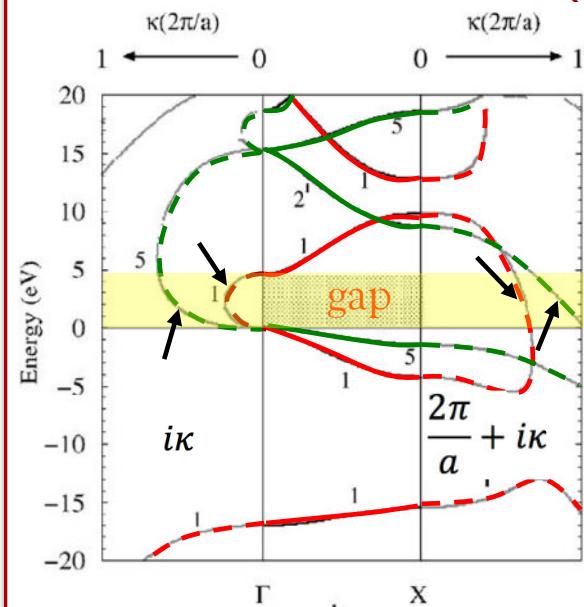
Their Bloch states adopt the same symmetries

## Fe band structure



Fe is a half metal for  $\Delta_1$

## MgO complex band structure

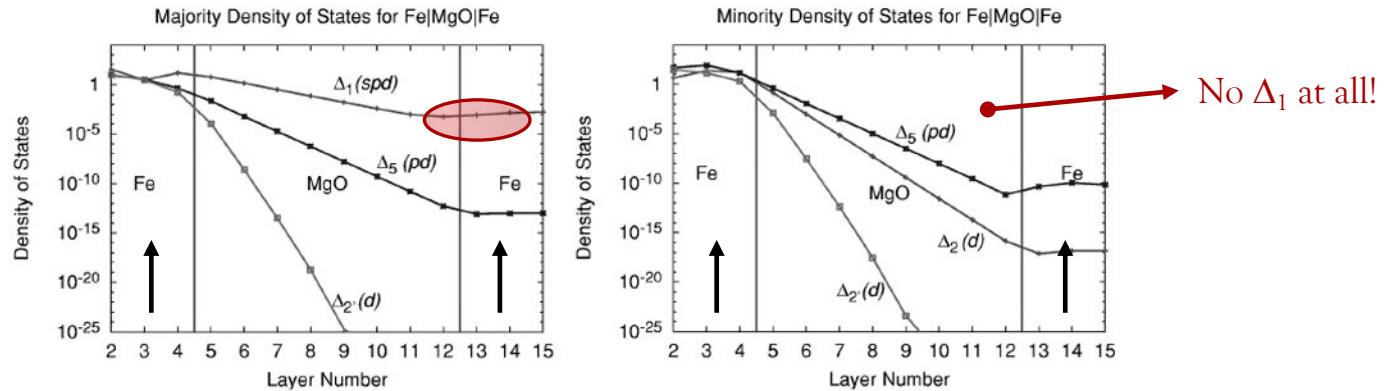


Dederichs et al., JMMM 240, 108 (2002)

MgO filters  $\Delta_1$  Bloch states!

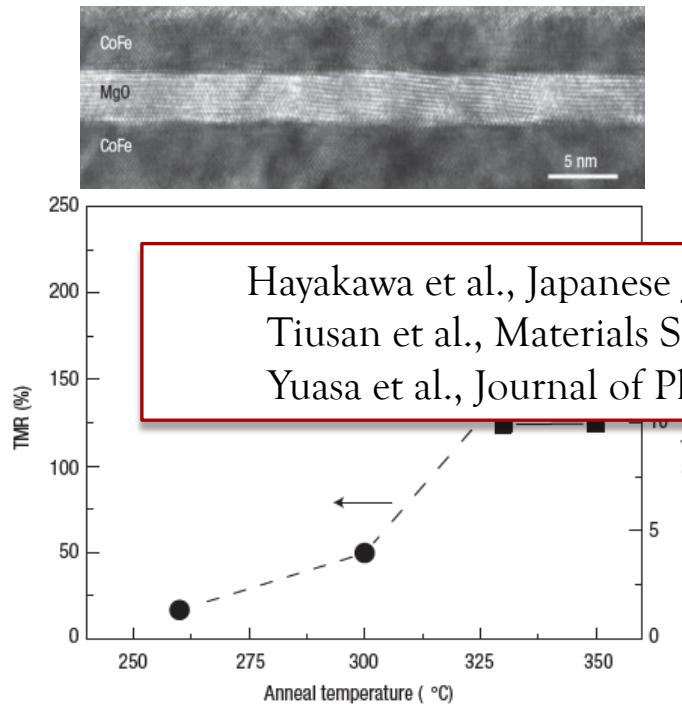
# MgO/Fe interfaces

## Bloch state filtering in Fe/MgO/Fe tunnel junction

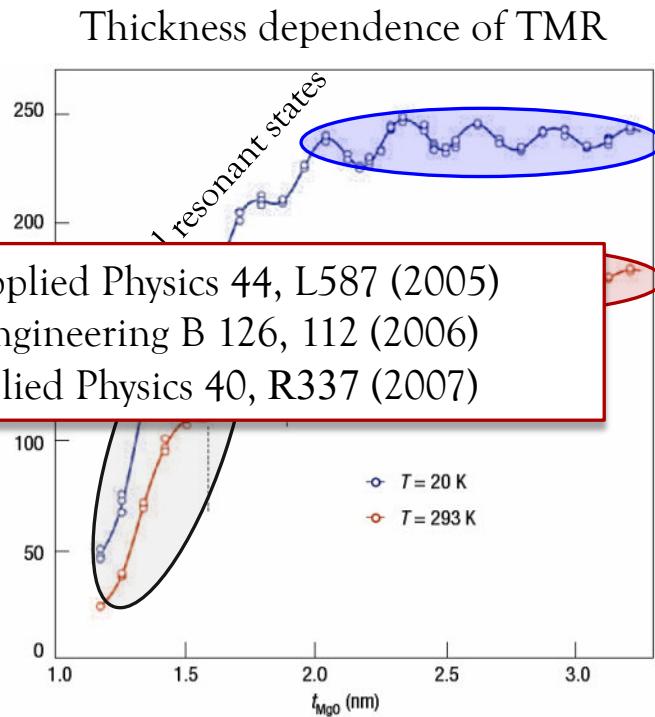


# MgO/Fe interfaces

## Epitaxial deposition of Fe/MgO/Fe junctions



Hayakawa et al., Japanese Journal of Applied Physics 44, L587 (2005)  
Tiusan et al., Materials Science and Engineering B 126, 112 (2006)  
Yuasa et al., Journal of Physics D: Applied Physics 40, R337 (2007)



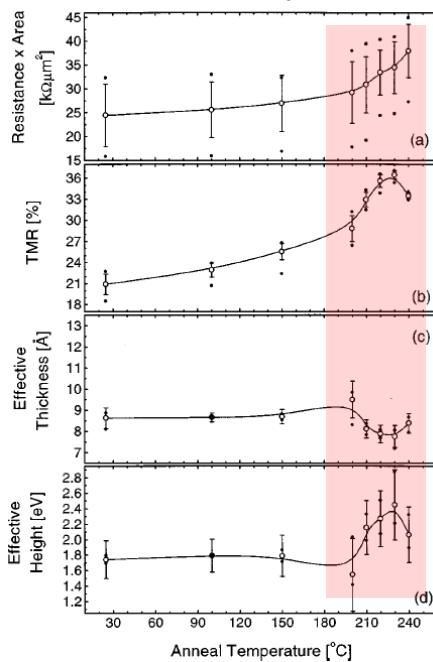
Parkin et al, Nature Materials 3, 862 (2004)

Yuasa et al., Nature Materials 3, 868 (2004)

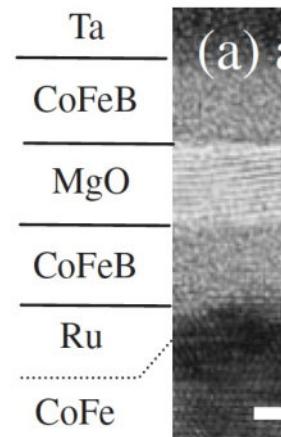
# Designing efficient magnetic tunnel junctions

- High TMR (>100%)
- Low resistance-area ( $\Omega \cdot \mu\text{m}^2$ )
- Optimal magnetic properties

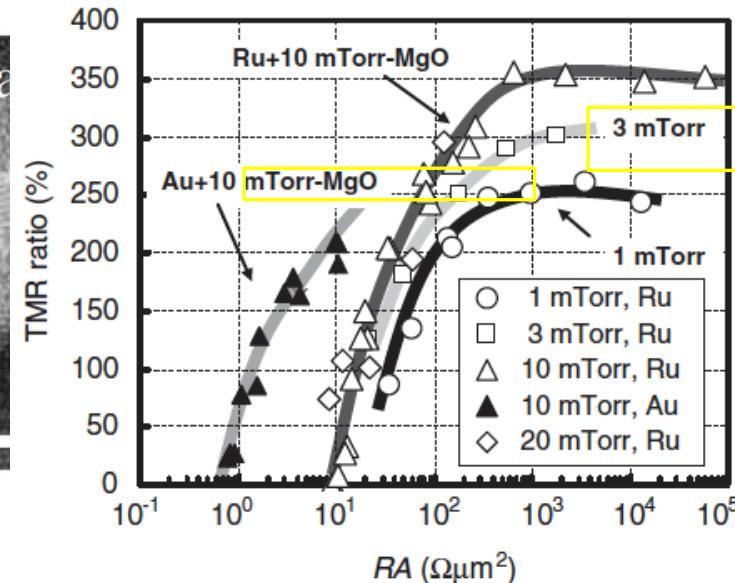
CoFe/Al<sub>2</sub>O<sub>3</sub>/CoFe



Sousa et al., Applied Physics Letters 73, 3288 (1998)

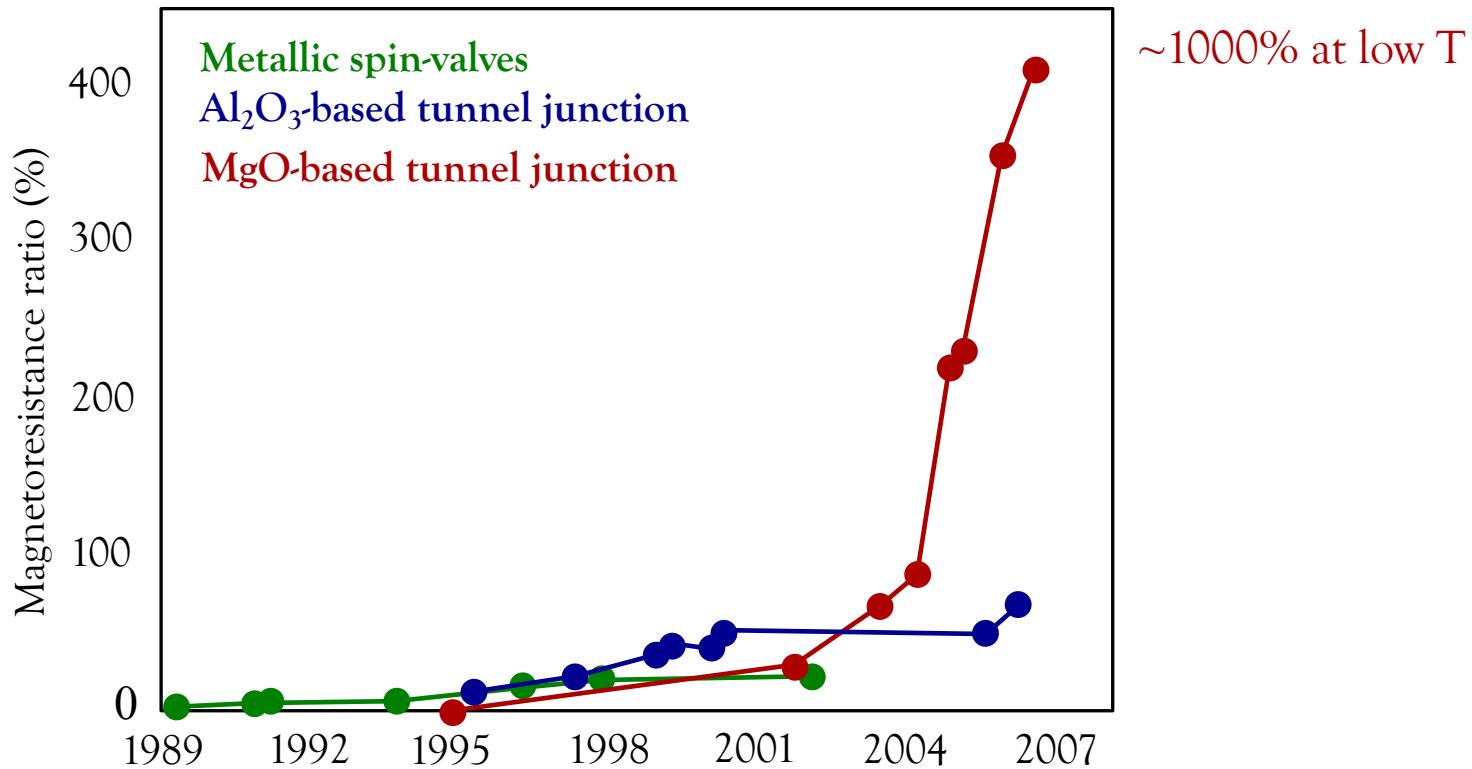


TMR ratio (%)



Hayakawa, Jap. Jour. Appl. Phys. 44, L587 (2005)

# Tunneling versus “giant” magnetoresistance



Heiliger and Mertig, Materials Today 9, 46 (2006)  
Ikeda et al., IEEE Trans. Elec. Dev. 54, 991 (2007)

BONUS!

BONUS!



# A tale of spinning balls



# A tale of spinning balls



# A tale of spinning balls



## The spinning ball spiral

Guillaume Dupeux, Anne Le Goff, David Quéré  
and Christophe Clanet<sup>1</sup>

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LadHyX, UMR7646 du CNRS, Ecole Polytechnique, 91128 Palaiseau, France  
E-mail: [clanet@ladhyx.polytechnique.fr](mailto:clanet@ladhyx.polytechnique.fr)

*New Journal of Physics* 12 (2010) 093004 (12pp)

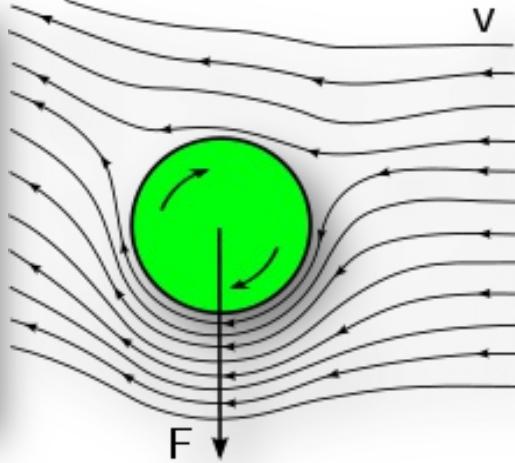
**Table 1.** Specifications for different sports. The first three sports are dominated by aerodynamic effects ( $\mathcal{L} \ll U_0^2/g$ ). For the last two sports, gravity dominates aerodynamics ( $\mathcal{L} \gg U_0^2/g$ ). In between, we identify sports for which both gravity and aerodynamics can be used to control the ball's trajectory. In this table,  $L$  is the size of the field except for baseball, where it stands for the distance between the pitcher and the batter.

Sport	$2R$ (cm)	$\rho_s/\rho$	$U_0$ (m s <sup>-1</sup> )	$S = R\omega_0/U_0$	$L$ (m)	$\mathcal{L}$ (m)	$U_0^2/g$ (m)	$d$ (m)
Table tennis	4.0	67	50	0.36	2.7	9.3	255	1
Golf	4.2	967	90	0.09	200	141	826	7
Tennis	6.5	330	70	0.19	24	73	499	5
Soccer	21	74	30	0.21	100	54	92	7
Baseball	7.0	654	40	0.17	18	160	163	7
Volleyball	21	49	20	0.21	18	35	41	5
Basketball	24	72	10		28	60	10	
Handball	19	108	20		40	71	40	

# A tale of spinning balls



Heinrich Magnus  
1802-1870



J.W.M. Bush, The aerodynamics of the beautiful game, 2013.  
In *Sports Physics*, Ed. C. Clanet, Les Editions de l'Ecole Polytechnique, p.171-192.